

(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property Organization
International Bureau



(43) International Publication Date
6 April 2006 (06.04.2006)

PCT

(10) International Publication Number
WO 2006/036542 A1

(51) International Patent Classification:
B81B 3/00 (2006.01) G02B 26/08 (2006.01)

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(21) International Application Number:

PCT/US2005/032647

(81) Designated States (unless otherwise indicated, for every
kind of national protection available): AE, AG, AL, AM,
AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN,
CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI,
GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE,
KG, KM, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, LY,
MA, MD, MG, MK, MN, MW, MX, MZ, NA, NG, NI, NO,
NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK,
SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ,
VC, VN, YU, ZA, ZM, ZW.

(22) International Filing Date:

15 September 2005 (15.09.2005)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data:

60/613,475 27 September 2004 (27.09.2004) US
11/208,809 22 August 2005 (22.08.2005) US

(84) Designated States (unless otherwise indicated, for every
kind of regional protection available): ARIPO (BW, GH,
GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM,
ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM),
European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI,
FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT,
RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA,
GN, GQ, GW, ML, MR, NE, SN, TD, TG).

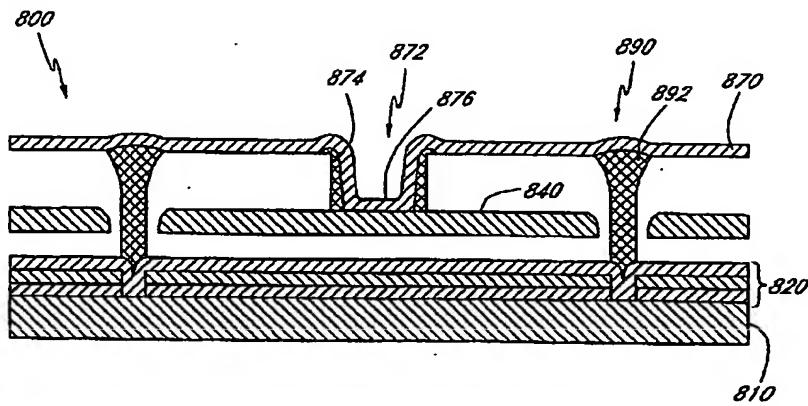
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Published:

— with international search report

[Continued on next page]

(54) Title: INTERFEROMETRIC OPTICAL MODULATOR USING FILLER MATERIAL AND METHOD



WO 2006/036542 A1

(57) Abstract: Described is an apparatus, method for manufacturing, and systems comprising a MEMS device, for example, an interferometric modulator, comprising a substrate, a movable mirror, a deformable layer, and a support structure. In some embodiments, the support structure comprises a plurality of support posts. A connector secures the movable mirror secured to the deformable layer. At least one of the connector and the support post is a composite comprising a first component and a second component, where at the first component forms at least a portion of at least one of the perimeter of the connector and support post.

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INTERFEROMETRIC OPTICAL MODULATOR USING FILLER MATERIAL AND METHOD

Background

Field of the Invention

[0001] This application is generally related to microelectromechanical systems devices, and more particularly, to optical modulators.

Description of the Related Technology

[0002] Microelectromechanical systems (MEMS) include micro mechanical elements, actuators, and electronics. Micromechanical elements may be created using deposition, etching, and/or other micromachining processes that etch away parts of substrates and/or deposited material layers or that add layers to form electrical and electromechanical devices. One type of MEMS device is called an interferometric modulator. As used herein, the term interferometric modulator or interferometric light modulator refers to a device that selectively absorbs and/or reflects light using the principles of optical interference. In certain embodiments, an interferometric modulator may comprise a pair of conductive plates, one or both of which may be transparent and/or reflective in whole or part and capable of relative motion upon application of an appropriate electrical signal. In a particular embodiment, one plate may comprise a stationary layer deposited on a substrate and the other plate may comprise a metallic membrane separated from the stationary layer by an air gap. As described herein in more detail, the position of one plate in relation to another can change the optical interference of light incident on the interferometric modulator. Such devices have a wide range of applications, and it would be beneficial in the art to utilize and/or modify the characteristics of these types of devices so that their features can be exploited in improving existing products and creating new products that have not yet been developed.

Summary

[0003] The system, method, and devices of the invention each have several aspects, no single one of which is solely responsible for its desirable attributes. Without limiting the scope of this invention, its more prominent features will now be discussed briefly. After considering this discussion, and particularly after reading the section entitled

"Detailed Description of Certain Embodiments" one will understand how the features of this invention provide advantages over other display devices.

[0004] Described herein is an apparatus, method for manufacturing, and systems comprising a MEMS device, for example, an interferometric optical modulator, comprising a substrate, a movable mirror, a deformable layer, and a support structure. In some embodiments, the support structure comprises a plurality of support posts. A connector secures the movable mirror to the deformable layer. At least one of the connector and the support post is a composite comprising a first component and a second component, where at the first component forms at least a portion of the perimeter of at least one of the connector and support post.

[0005] Accordingly, one embodiment described herein provides a microelectromechanical systems device comprising: a substrate; a deformable layer; a support structure supporting the deformable layer; a movable conductor positioned between the substrate and the deformable layer; and at least one connector securing the movable conductor to the deformable layer. At least one of the connector and the support structure comprises a first component and a second component, at least a portion of the first component is disposed on the perimeter of at least one of the connector and the support structure; and the first component comprises an electrically insulating filler material.

[0006] Another embodiment provides a method for fabricating an optical modulator and an optical modulator fabricated thereby, the method comprising: forming over a substrate, a layer of a first sacrificial material, a mirror, and a layer of a second sacrificial material; forming a first opening through the layer of the second sacrificial material thereby exposing the mirror; and filling at least a portion of the sides of the opening with a filler material.

[0007] Another embodiment provides a microelectromechanical systems device comprising: a deformable conductive layer; a movable conductive layer; an electrically conductive core extending between the deformable conductive layer and the movable conductive layer; and a layer of an electrically insulating material surrounding the conductive core.

[0008] Another embodiment provides a microelectromechanical systems device comprising: a substrate; a layer of a first sacrificial material formed over the substrate; a conductor formed over the layer of the first sacrificial material; a layer of a second sacrificial material formed over the conductor; a first opening through the layer of the second sacrificial material, wherein the first opening exposes the conductor; and a means for filling discontinuities in first opening with a filler material. Some embodiments further comprise: a deformable layer formed over the layer of the second sacrificial material; and a plurality of posts extending between the substrate and the deformable layer.

[0009] Another embodiment provides a microelectromechanical systems device comprising: a movable means; a support means for supporting the movable means; a conductive means for communicating electrical signals between the movable means and the means for supporting the movable means; and a filler means for facilitating formation of the means for communicating electrical signals.

[0010] Another embodiment provides a method for operating a microelectromechanical systems device. The microelectromechanical systems device comprises: a compartment; a deformable conductive layer; a movable conductive layer, wherein the movable conductive layer is movable between a first position and a second position in the compartment; an electrically conductive core extending between the deformable conductive layer and the movable conductive layer; and a layer of an electrically insulating material surrounding the conductive core. The method comprises applying a first voltage to the movable conductive layer sufficient to move the movable conductive layer from the first position to the second position.

Brief Description of the Drawings

[0011] These and other aspects of the invention will be readily apparent from the following description and from the appended drawings (not to scale), which are meant to illustrate and not to limit the invention.

[0012] FIG. 1 is an isometric view depicting a portion of one embodiment of an interferometric modulator display in which a movable reflective layer of a first interferometric modulator is in a relaxed position and a movable reflective layer of a second interferometric modulator is in an actuated position.

[0013] FIG. 2 is a system block diagram illustrating one embodiment of an electronic device incorporating a 3×3 interferometric modulator display.

[0014] FIG. 3 is a diagram of movable mirror position versus applied voltage for one exemplary embodiment of an interferometric modulator of FIG. 1.

[0015] FIG. 4 is an illustration of a set of row and column voltages that may be used to drive an interferometric modulator display.

[0016] FIG. 5A illustrates one exemplary frame of display data in the 3×3 interferometric modulator display of FIG. 2.

[0017] FIG. 5B illustrates one exemplary timing diagram for row and column signals that may be used to write the frame of FIG. 5A.

[0018] FIG. 6A and FIG. 6B are system block diagrams illustrating an embodiment of a visual display device comprising a plurality of interferometric modulators.

[0019] FIG. 7A is a cross section of the device of FIG. 1. FIG. 7B is a cross section of an alternative embodiment of an interferometric modulator. FIG. 7C is a cross section of another alternative embodiment of an interferometric modulator. FIG. 7D is a cross section of yet another alternative embodiment of an interferometric modulator. FIG. 7E is a cross section of an additional alternative embodiment of an interferometric modulator.

[0020] FIG. 8A-FIG. 8E illustrate embodiments of an interferometric modulator comprising a composite connector as disclosed herein. FIG. 8F-FIG. 8M illustrate intermediate structures in an embodiment of the fabrication of the apparatus illustrated in FIG. 8A.

[0021] FIG. 9A-FIG. 9F illustrate another embodiment of an interferometric modulator as disclosed herein and intermediate structures in an embodiment of its fabrication.

[0022] FIG. 10A-FIG. 10D illustrate another embodiment of an interferometric modulator as disclosed herein and intermediate structures in an embodiment of its fabrication.

[0023] FIG. 11 is a flowchart illustrating an embodiment of a method for synthesizing an interferometric modulator as disclosed herein.

[0024] FIG. 12A illustrates various defects in a deformable layer. FIG. 12B illustrates representative contact angles (θ) for the filler material.

Detailed Description of Certain Embodiments

[0025] The following detailed description is directed to certain specific embodiments of the invention. However, the invention can be embodied in a multitude of different ways. In this description, reference is made to the drawings wherein like parts are designated with like numerals throughout. As will be apparent from the following description, the embodiments may be implemented in any device that is configured to display an image, whether in motion (e.g., video) or stationary (e.g., still image), and whether textual or pictorial. More particularly, it is contemplated that the embodiments may be implemented in or associated with a variety of electronic devices such as, but not limited to, mobile telephones, wireless devices, personal data assistants (PDAs), hand-held or portable computers, GPS receivers/navigators, cameras, MP3 players, camcorders, game consoles, wrist watches, clocks, calculators, television monitors, flat panel displays, computer monitors, auto displays (e.g., odometer display, etc.), cockpit controls and/or displays, display of camera views (e.g., display of a rear view camera in a vehicle), electronic photographs, electronic billboards or signs, projectors, architectural structures, packaging, and aesthetic structures (e.g., display of images on a piece of jewelry). MEMS devices of similar structure to those described herein can also be used in non-display applications such as in electronic switching devices.

[0026] Embodiments of the MEMS device disclosed herein comprise a composite connector securing the movable mirror to the deformable layer. The composite connector comprises a first component and a second component, wherein the first component comprises a filler material. In some embodiments, at least a portion of the first component of the connector is disposed on the perimeter of the connector. In some embodiments, the first component forms the sides of at least a portion of the connector, for example, a collar around the lower portion of the connector. In other embodiments, the first component is annular, forming the entire sides of the connector and completely surrounding the sides' second component. Embodiments of the device also comprise composite support posts. The composite support posts comprise a first component and a second component, wherein the

first component comprises a filler material. In some embodiments, at least a portion of the first component is disposed on the perimeter of the support post. Embodiments of the disclosed device are more easily fabricated than similar devices using non-composite connectors. For example, in some embodiments, the filler material is applied in a spin-on process. In some embodiments, the filler material provides a surface on the device upon which a layer of a predetermined material is more easily formed than on an equivalent device without the filler material.

[0027] One interferometric modulator display embodiment comprising an interferometric MEMS display element is illustrated in FIG. 1. In these devices, the pixels are in either a bright or dark state. In the bright ("on" or "open") state, the display element reflects a large portion of incident visible light to a user. When in the dark ("off" or "closed") state, the display element reflects little incident visible light to the user. Depending on the embodiment, the light reflectance properties of the "on" and "off" states may be reversed. MEMS pixels can be configured to reflect predominantly at selected colors, allowing for a color display in addition to black and white.

[0028] FIG. 1 is an isometric view depicting two adjacent pixels in a series of pixels of a visual display, wherein each pixel comprises a MEMS interferometric modulator. In some embodiments, an interferometric modulator display comprises a row/column array of these interferometric modulators. Each interferometric modulator includes a pair of reflective layers positioned at a variable and controllable distance from each other to form a resonant optical cavity with at least one variable dimension. In one embodiment, one of the reflective layers may be moved between two positions. In the first position, referred to herein as the relaxed position, the movable reflective layer is positioned at a relatively large distance from a fixed partially reflective layer. In the second position, referred to herein as the actuated position, the movable reflective layer is positioned more closely adjacent to the partially reflective layer. Incident light that reflects from the two layers interferes constructively or destructively depending on the position of the movable reflective layer, producing either an overall reflective or non-reflective state for each pixel.

[0029] The depicted portion of the pixel array in FIG. 1 includes two adjacent interferometric modulators 12a and 12b. In the interferometric modulator 12a on the left, a

movable reflective layer 14a is illustrated in a relaxed position at a predetermined distance from an optical stack 16a, which includes a partially reflective layer. In the interferometric modulator 12b on the right, the movable reflective layer 14b is illustrated in an actuated position adjacent to the optical stack 16b.

[0030] The optical stacks 16a and 16b (collectively referred to as optical stack 16), as referenced herein, typically comprise of several fused layers, which can include an electrode layer, such as indium tin oxide (ITO), a partially reflective layer, such as chromium, and a transparent dielectric. The optical stack 16 is thus electrically conductive, partially transparent and partially reflective, and may be fabricated, for example, by depositing one or more of the above layers onto a transparent substrate 20. In some embodiments, the layers are patterned into parallel strips, and may form row electrodes in a display device as described further below. The movable reflective layers 14a, 14b may be formed as a series of parallel strips of a deposited metal layer or layers (orthogonal to the row electrodes of 16a, 16b) deposited on top of posts 18 and an intervening sacrificial material deposited between the posts 18. When the sacrificial material is etched away, the movable reflective layers 14a, 14b are separated from the optical stacks 16a, 16b by a defined gap 19. A highly conductive and reflective material such as aluminum may be used for the reflective layers 14, and these strips may form column electrodes in a display device.

[0031] With no applied voltage, the cavity 19 remains between the movable reflective layer 14a and optical stack 16a, with the movable reflective layer 14a in a mechanically relaxed state, as illustrated by the pixel 12a in FIG. 1. However, when a potential difference is applied to a selected row and column, the capacitor formed at the intersection of the row and column electrodes at the corresponding pixel becomes charged, and electrostatic forces pull the electrodes together. If the voltage is high enough, the movable reflective layer 14 is deformed and is forced against the optical stack 16. A dielectric layer (not illustrated in this Figure) within the optical stack 16 may prevent shorting and control the separation distance between layers 14 and 16, as illustrated by pixel 12b on the right in FIG. 1. The behavior is the same regardless of the polarity of the applied potential difference. In this way, row/column actuation that can control the reflective vs.

non-reflective pixel states is analogous in many ways to that used in conventional LCD and other display technologies.

[0032] FIG. 2 through FIG. 5 illustrate one exemplary process and system for using an array of interferometric modulators in a display application.

[0033] FIG. 2 is a system block diagram illustrating one embodiment of an electronic device that may incorporate aspects of the invention. In the exemplary embodiment, the electronic device includes a processor 21 which may be any general purpose single- or multi-chip microprocessor such as an ARM, Pentium®, Pentium II®, Pentium III®, Pentium IV®, Pentium® Pro, an 8051, a MIPS®, a Power PC®, an ALPHA®, or any special purpose microprocessor such as a digital signal processor, microcontroller, or a programmable gate array. As is conventional in the art, the processor 21 may be configured to execute one or more software modules. In addition to executing an operating system, the processor may be configured to execute one or more software applications, including a web browser, a telephone application, an email program, or any other software application.

[0034] In one embodiment, the processor 21 is also configured to communicate with an array driver 22. In one embodiment, the array driver 22 includes a row driver circuit 24 and a column driver circuit 26 that provide signals to a panel or display array (display) 30. The cross section of the array illustrated in FIG. 1 is shown by the lines 1-1 in FIG. 2. For MEMS interferometric modulators, the row/column actuation protocol may take advantage of a hysteresis property of these devices illustrated in FIG. 3. It may require, for example, a 10 volt potential difference to cause a movable layer to deform from the relaxed state to the actuated state. However, when the voltage is reduced from that value, the movable layer maintains its state as the voltage drops back below 10 volts. In the exemplary embodiment of FIG. 3, the movable layer does not relax completely until the voltage drops below 2 volts. There is thus a range of voltage, about 3 to 7 V in the example illustrated in FIG. 3, where there exists a window of applied voltage within which the device is stable in either the relaxed or actuated state. This is referred to herein as the "hysteresis window" or "stability window." For a display array having the hysteresis characteristics of FIG. 3, the row/column actuation protocol can be designed such that during row strobing, pixels in the strobed row that are to be actuated are exposed to a voltage difference of about 10 volts, and pixels that

are to be relaxed are exposed to a voltage difference of close to zero volts. After the strobe, the pixels are exposed to a steady state voltage difference of about 5 volts such that they remain in whatever state the row strobe put them in. After being written, each pixel sees a potential difference within the "stability window" of 3–7 volts in this example. This feature makes the pixel design illustrated in FIG. 1 stable under the same applied voltage conditions in either an actuated or relaxed pre-existing state. Since each pixel of the interferometric modulator, whether in the actuated or relaxed state, is essentially a capacitor formed by the fixed and moving reflective layers, this stable state can be held at a voltage within the hysteresis window with almost no power dissipation. Essentially no current flows into the pixel if the applied potential is fixed.

[0035] In typical applications, a display frame may be created by asserting the set of column electrodes in accordance with the desired set of actuated pixels in the first row. A row pulse is then applied to the row 1 electrode, actuating the pixels corresponding to the asserted column lines. The asserted set of column electrodes is then changed to correspond to the desired set of actuated pixels in the second row. A pulse is then applied to the row 2 electrode, actuating the appropriate pixels in row 2 in accordance with the asserted column electrodes. The row 1 pixels are unaffected by the row 2 pulse, and remain in the state they were set to during the row 1 pulse. This may be repeated for the entire series of rows in a sequential fashion to produce the frame. Generally, the frames are refreshed and/or updated with new display data by continually repeating this process at some desired number of frames per second. A wide variety of protocols for driving row and column electrodes of pixel arrays to produce display frames are also well known and may be used in conjunction with the present invention.

[0036] FIG. 4 and FIG. 5 illustrate one possible actuation protocol for creating a display frame on the 3×3 array of FIG. 2. FIG. 4 illustrates a possible set of column and row voltage levels that may be used for pixels exhibiting the hysteresis curves of FIG. 3. In the FIG. 4 embodiment, actuating a pixel involves setting the appropriate column to $-V_{bias}$, and the appropriate row to $+\Delta V$, which may correspond to -5 volts and +5 volts respectively. Relaxing the pixel is accomplished by setting the appropriate column to $+V_{bias}$, and the appropriate row to the same $+\Delta V$, producing a zero volt potential difference across the pixel.

In those rows where the row voltage is held at zero volts, the pixels are stable in whatever state they were originally in, regardless of whether the column is at $+V_{bias}$, or $-V_{bias}$. As is also illustrated in FIG. 4, it will be appreciated that voltages of opposite polarity than those described above can be used, e.g., actuating a pixel can involve setting the appropriate column to $+V_{bias}$, and the appropriate row to $-\Delta V$. In this embodiment, releasing the pixel is accomplished by setting the appropriate column to $-V_{bias}$, and the appropriate row to the same $-\Delta V$, producing a zero volt potential difference across the pixel.

[0037] FIG. 5B is a timing diagram showing a series of row and column signals applied to the 3×3 array of FIG. 2 which will result in the display arrangement illustrated in FIG. 5A, where actuated pixels are non-reflective. Prior to writing the frame illustrated in FIG. 5A, the pixels can be in any state, and in this example, all the rows are at 0 volts, and all the columns are at +5 volts. With these applied voltages, all pixels are stable in their existing actuated or relaxed states.

[0038] In the FIG. 5A frame, pixels (1,1), (1,2), (2,2), (3,2) and (3,3) are actuated. To accomplish this, during a “line time” for row 1, columns 1 and 2 are set to -5 volts, and column 3 is set to +5 volts. This does not change the state of any pixels, because all the pixels remain in the 3–7 volt stability window. Row 1 is then strobed with a pulse that goes from 0, up to 5 volts, and back to zero. This actuates the (1,1) and (1,2) pixels and relaxes the (1,3) pixel. No other pixels in the array are affected. To set row 2 as desired, column 2 is set to -5 volts, and columns 1 and 3 are set to +5 volts. The same strobe applied to row 2 will then actuate pixel (2,2) and relax pixels (2,1) and (2,3). Again, no other pixels of the array are affected. Row 3 is similarly set by setting columns 2 and 3 to -5 volts, and column 1 to +5 volts. The row 3 strobe sets the row 3 pixels as shown in FIG. 5A. After writing the frame, the row potentials are zero, and the column potentials can remain at either +5 or -5 volts, and the display is then stable in the arrangement of FIG. 5A. It will be appreciated that the same procedure can be employed for arrays of dozens or hundreds of rows and columns. It will also be appreciated that the timing, sequence, and levels of voltages used to perform row and column actuation can be varied widely within the general principles outlined above, and the above example is exemplary only, and any actuation voltage method can be used with the systems and methods described herein.

[0039] FIG. 6A and FIG. 6B are system block diagrams illustrating an embodiment of a display device 40. The display device 40 can be, for example, a cellular or mobile telephone. However, the same components of the display device 40 or slight variations thereof are also illustrative of various types of display devices such as televisions and portable media players.

[0040] The display device 40 includes a housing 41, a display 30, an antenna 43, a speaker 45, an input device 48, and a microphone 46. The housing 41 is generally formed from any of a variety of manufacturing processes as are well known to those of skill in the art, including injection molding, and vacuum forming. In addition, the housing 41 may be made from any of a variety of materials, including but not limited to plastic, metal, glass, rubber, and ceramic, or a combination thereof. In one embodiment the housing 41 includes removable portions (not shown) that may be interchanged with other removable portions of different color, or containing different logos, pictures, or symbols.

[0041] The display 30 of the exemplary display device 40 may be any of a variety of displays, including a bi-stable display, as described herein. In other embodiments, the display 30 includes a flat-panel display, such as plasma, EL, OLED, STN LCD, or TFT LCD as described above, or a non-flat-panel display, such as a CRT or other tube device, as is well known to those of skill in the art. However, for purposes of describing the present embodiment, the display 30 includes an interferometric modulator display, as described herein.

[0042] The components of one embodiment of the exemplary display device 40 are schematically illustrated in FIG. 6B. The illustrated exemplary display device 40 includes a housing 41 and can include additional components at least partially enclosed therein. For example, in one embodiment, the exemplary display device 40 includes a network interface 27 that includes an antenna 43 which is coupled to a transceiver 47. The transceiver 47 is connected to the processor 21, which is connected to conditioning hardware 52. The conditioning hardware 52 may be configured to condition a signal (e.g. filter a signal). The conditioning hardware 52 is connected to a speaker 45 and a microphone 46. The processor 21 is also connected to an input device 48 and a driver controller 29. The driver controller 29 is coupled to a frame buffer 28 and to the array driver 22, which in turn is

coupled to a display array 30. A power supply 50 provides power to all components as required by the particular exemplary display device 40 design.

[0043] The network interface 27 includes the antenna 43 and the transceiver 47 so that the exemplary display device 40 can communicate with one or more devices over a network. In one embodiment the network interface 27 may also have some processing capabilities to relieve requirements of the processor 21. The antenna 43 is any antenna known to those of skill in the art for transmitting and receiving signals. In one embodiment, the antenna transmits and receives RF signals according to the IEEE 802.11 standard, including IEEE 802.11(a), (b), or (g). In another embodiment, the antenna transmits and receives RF signals according to the BLUETOOTH standard. In the case of a cellular telephone, the antenna is designed to receive CDMA, GSM, AMPS or other known signals that are used to communicate within a wireless cell phone network. The transceiver 47 pre-processes the signals received from the antenna 43 so that they may be received by and further manipulated by the processor 21. The transceiver 47 also processes signals received from the processor 21 so that they may be transmitted from the exemplary display device 40 via the antenna 43.

[0044] In an alternative embodiment, the transceiver 47 can be replaced by a receiver. In yet another alternative embodiment, the network interface 27 can be replaced by an image source, which can store or generate image data to be sent to the processor 21. For example, the image source can be a digital video disc (DVD) or a hard-disc drive that contains image data, or a software module that generates image data.

[0045] The processor 21 generally controls the overall operation of the exemplary display device 40. The processor 21 receives data, such as compressed image data from the network interface 27 or an image source, and processes the data into raw image data or into a format that is readily processed into raw image data. The processor 21 then sends the processed data to the driver controller 29 or to the frame buffer 28 for storage. Raw data typically refers to the information that identifies the image characteristics at each location within an image. For example, such image characteristics can include color, saturation, and gray-scale level.

[0046] In one embodiment, the processor 21 includes a microcontroller, CPU, or logic unit to control operation of the exemplary display device 40. The conditioning hardware 52 generally includes amplifiers and filters for transmitting signals to the speaker 45, and for receiving signals from the microphone 46. The conditioning hardware 52 may be discrete components within the exemplary display device 40, or may be incorporated within the processor 21 or other components.

[0047] The driver controller 29 takes the raw image data generated by the processor 21 either directly from the processor 21 or from the frame buffer 28 and reformats the raw image data appropriately for high speed transmission to the array driver 22. Specifically, the driver controller 29 reformats the raw image data into a data flow having a raster-like format, such that it has a time order suitable for scanning across the display array 30. Then the driver controller 29 sends the formatted information to the array driver 22. Although a driver controller 29, such as a LCD controller, is often associated with the system processor 21 as a stand-alone Integrated Circuit (IC), such controllers may be implemented in many ways. They may be embedded in the processor 21 as hardware, embedded in the processor 21 as software, or fully integrated in hardware with the array driver 22.

[0048] Typically, the array driver 22 receives the formatted information from the driver controller 29 and reformats the video data into a parallel set of waveforms that are applied many times per second to the hundreds and sometimes thousands of leads coming from the display's x-y matrix of pixels.

[0049] In one embodiment, the driver controller 29, array driver 22, and display array 30 are appropriate for any of the types of displays described herein. For example, in one embodiment, the driver controller 29 is a conventional display controller or a bi-stable display controller (e.g., an interferometric modulator controller). In another embodiment, the array driver 22 is a conventional driver or a bi-stable display driver (e.g., an interferometric modulator display). In one embodiment, the driver controller 29 is integrated with the array driver 22. Such an embodiment is common in highly integrated systems such as cellular phones, watches, and other small area displays. In yet another embodiment, the display array 30 is a typical display array or a bi-stable display array (e.g., a display including an array of interferometric modulators).

[0050] The input device 48 allows a user to control the operation of the exemplary display device 40. In one embodiment, the input device 48 includes a keypad, such as a QWERTY keyboard or a telephone keypad, a button, a switch, a touch-sensitive screen, a pressure- or heat-sensitive membrane. In one embodiment, the microphone 46 is an input device for the exemplary display device 40. When the microphone 46 is used to input data to the device, voice commands may be provided by a user for controlling operations of the exemplary display device 40.

[0051] The power supply 50 can include a variety of energy storage devices as are well known in the art. For example, in one embodiment, the power supply 50 is a rechargeable battery, such as a nickel-cadmium battery or a lithium ion battery. In another embodiment, the power supply 50 is a renewable energy source, a capacitor, or a solar cell, including a plastic solar cell, and solar-cell paint. In another embodiment, the power supply 50 is configured to receive power from a wall outlet.

[0052] In some implementations control programmability resides, as described above, in a driver controller which can be located in several places in the electronic display system. In some cases control programmability resides in the array driver 22. Those of skill in the art will recognize that the above-described optimization may be implemented in any number of hardware and/or software components and in various configurations.

[0053] The details of the structure of interferometric modulators that operate in accordance with the principles set forth above may vary widely. For example, FIG. 7A–FIG. 7E illustrate five different embodiments of the movable reflective layer 14 and its supporting structures. FIG. 7A is a cross section of the embodiment of FIG. 1, where a strip of metal material 14 is deposited on orthogonally extending supports 18. In FIG. 7B, the moveable reflective layer 14 is attached to supports at the corners only, on tethers 32. In FIG. 7C, the moveable reflective layer 14 is suspended from a deformable layer 34, which may comprise a flexible metal. The deformable layer 34 connects, directly or indirectly, to the substrate 20 around the perimeter of the deformable layer 34. These connections are herein referred to as the support posts 18. The embodiment illustrated in FIG. 7D has support posts 18 that include support post plugs 42 upon which the deformable layer 34 rests. The moveable reflective layer 14 remains suspended over the cavity, as in FIG. 7A–FIG. 7C,

but the deformable layer 34 does not form the support posts by filling holes between the deformable layer 34 and the optical stack 16. Rather, the support posts 18 are formed of a planarization material, which is used to form the support post plugs 42. The embodiment illustrated in **FIG. 7E** is based on the embodiment shown in **FIG. 7D**, but may also be adapted to work with any of the embodiments illustrated in **FIG. 7A–FIG. 7C** as well as additional embodiments not shown. In the embodiment shown in **FIG. 7E**, an extra layer of metal or other conductive material has been used to form a bus structure 44. This allows signal routing along the back of the interferometric modulators, eliminating a number of electrodes that may otherwise have had to be formed on the substrate 20.

[0054] In embodiments such as those shown in **FIG. 7**, the interferometric modulators function as direct-view devices, in which images are viewed from the front side of the transparent substrate 20, the side opposite to that upon which the modulator is arranged. In these embodiments, the reflective layer 14 optically shields some portions of the interferometric modulator on the side of the reflective layer opposite the substrate 20, including the deformable layer 34 and the bus structure 44. This allows the shielded areas to be configured and operated upon without negatively affecting the image quality. This separable modulator architecture allows the structural design and materials used for the electromechanical aspects and the optical aspects of the modulator to be selected and to function independently of each other. Moreover, the embodiments shown in **FIG. 7C–FIG. 7E** have additional benefits deriving from the decoupling of the optical properties of the reflective layer 14 from its mechanical properties, which are carried out by the deformable layer 34. This allows the structural design and materials used for the reflective layer 14 to be optimized with respect to the optical properties, and the structural design and materials used for the deformable layer 34 to be optimized with respect to desired mechanical properties.

[0055] The MEMS devices, structures, methods, and systems described below are optical modulators. The teachings herein are also applicable to other types of MEMS devices, as will be apparent to those skilled in the art. Those skilled in the art will also understand that the teachings are also applicable to optical modulators of other types, for example optical modulators as described above and illustrated in **FIG. 7A–FIG. 7E**.

[0056] **FIG. 8A** illustrates in cross-section an embodiment of an optical modulator 800 similar to the device illustrated in **FIG. 7D**. The optical modulator 800 comprises a substrate 810, an optical stack 820, a movable mirror 840, a deformable layer 870, and a plurality of support posts 890. The support posts 890 collectively form a support structure. In embodiments in which the MEMS device is not an optical modulator, the optical stack 820 is optional. In some embodiments, at least a portion of the movable mirror 840 is electrically conductive. Some embodiments in which the MEMS device is not an optical modulator comprise a movable mirror that does not comprise a reflective surface. In these embodiments, the movable mirror is referred to as a "movable conductor." Securing the movable mirror 840 to the deformable layer 870 is a composite connector 872 comprising a first component 874 and a second component 876. In some embodiments, the first component 874 of the connector comprises a filler material and the second part 876 comprises another material. In some preferred embodiments, the filler material is a spin-on and/or self-planarizing material. The filler material is discussed in greater detail below. In some embodiments, at least one of the first component 874 or the second component 876 is electrically conductive. Details on the structure of the composite connector 872 and suitable materials are discussed below. In other embodiments, the optical modulator 800 comprises a plurality of connectors 872. In the illustrated embodiment, the support posts 890 comprise support post plugs 892 comprising a filler material.

[0057] **FIG. 8B** is a top view of an embodiment of an optical modulator 800. The cross section illustrated in **FIG. 8A** is indicated by section 8A-8A. **FIG. 8B** illustrates the deformable layer 870, support posts 890, movable mirror 840 and the composite connector 872. In the illustrated embodiment, the composite connector 872 is substantially circular. In other embodiments, the composite connector 872 has another shape, for example, square, rectangular, hexagonal, elliptical, or other regular and irregular shapes. As discussed above, the composite connector 872 comprises a first component 874 and a second component 876. Returning to **FIG. 8A**, in the illustrated embodiment, the first component 874 is disposed around the periphery of the composite connector 872. In some embodiments, the first component 874 is shaped like a collar, forming the sides of at least a part of the composite connector 872. For example, in the embodiment illustrated in **FIG. 8B**, the first component

874 is annular and surrounds at least a portion of the outer sidewall of the second component 876. In other embodiments the first component 874 comprises one or more sections that do not surround or form a complete perimeter around any part of the connector 872, for example, as illustrated in top view in FIG. 8C and FIG. 8D. In the embodiment illustrated in FIG. 8A, the first component 874 forms the entirety of the sides of the connector 872, covering substantially the entire outer sidewall of the second component 876. In other embodiments, the first component 874 does not completely cover the sides of the second component 876. For example, FIG. 8E illustrates a cross section of a connector 872 comprising a first component 874 that forms the sides of the lower portion of the connector 872, but not the sides of the upper portion. In the illustrated embodiment, the first component 874 contacts the mirror 840, but does not extend to the full height of the connector 872.

[0058] Returning to FIG. 8A, in the illustrated embodiment, the second component 876 of the composite connector is integrated with the deformable layer 870 and secures the mirror 840 to the deformable layer 870. As illustrated, the second component 876 nests within the first component 874, forming a hollow, concave structure. The bottom of the second component 856 contacts the conductive mirror 840, forming an electrical connection through which electrical signals may be sent to the mirror 840, as described above. Because the second component 856 is integrated with the deformable layer 870 in the illustrated embodiment, both structures comprise the same material. A method for manufacturing the device illustrated in FIG. 8A is described below with reference to FIG. 8F-FIG. 8M. As discussed below, in other embodiments, the second component is not integrated with the deformable layer 870, has a different shape, and/or comprises a material different from the deformable layer 870.

[0059] FIG. 9A illustrates in cross section another embodiment of an interferometric modulator 900 comprising a substrate 910, and optical stack 920, a movable mirror 940, a deformable layer 970, and a plurality of support posts 990. A composite connector 972 secures the movable mirror 940 to the deformable layer 970. In the illustrated embodiment, the composite connector 972 comprises an annular first component 974 that forms the sides of the composite connector 972. A second component 976 forms a core in

the connector 972. In the illustrated embodiment, the second component 976 is substantially entirely enclosed by the first component 974, the movable conductor 940, and the deformable layer 970. In some embodiments, at least one of the first component 974 and the second component 976 is electrically conductive, thereby electrically connecting the movable conductor 940 and the deformable layer 970 as discussed above. A method for manufacturing the embodiment of the device illustrated in FIG. 9A is described below with reference to FIG. 9B-FIG. 9F.

[0060] FIG. 10A illustrates in cross section an embodiment of an interferometric modulator 1000 comprising a substrate 1010, an optical stack 1020, a movable mirror 1040, a deformable layer 1070, and a plurality of support posts 1090. The illustrated embodiment comprises a composite connector 1072 comprising a first component 1074 and a second component 1076. The composite connector 1072 is similar to the composite connector 872 illustrated in FIG. 8A and described above. In other embodiments, the connector is not a composite connector, for example, similar to the connector 36 (FIG. 7D). In the illustrated embodiment, the support posts 1090 are composite, comprising a first component 1094 and a second component 1096. In the illustrated embodiment, the first component 1094 is disposed around the periphery of the composite support post 1090. In some preferred embodiments, the first component 1094 is annular, surrounding at least the sides of a lower portion of the second component 1096 of the support post, for example, as illustrated in FIG. 10B. In some preferred embodiments, the first component 1094 substantially entirely surrounds the sides of the second component 1096, thereby forming the sides of the support post 1090, as illustrated in FIG. 10A. In other embodiments the first component 1094 comprises one or more sections that do not form a closed structure around the second component 1096.

[0061] FIG. 11 is a flowchart illustrating an embodiment of a method for fabricating a MEMS device, with reference to the interferometric modulator 800 illustrated in FIG. 8A and FIG. 8F-FIG. 8M, which illustrate intermediate structures in the method.

[0062] In step 1110, an optical stack 820 is formed on the substrate 810. In some embodiments, the optical stack 820 comprises an electrode layer 822, a partially reflective layer 824, and a dielectric layer 826, as illustrated in FIG. 8F. In the illustrated embodiment, the electrode layer 822 and partially reflective layer 824 are formed on the substrate 820 and

patterned to open support regions, which in some preferred embodiments, define rows of lower electrode (not shown). The dielectric layer 826 is then formed thereon.

[0063] In step 1120, a first sacrificial layer 830 is formed over the optical stack 820, as illustrated in FIG. 8G. The first sacrificial layer 830 comprises a first sacrificial material. Suitable sacrificial materials are known in the art, for example, inorganic sacrificial materials and organic sacrificial materials. Examples of suitable inorganic sacrificial materials include silicon, titanium, zirconium, hafnium, vanadium, tantalum, niobium, molybdenum, and tungsten. Examples of suitable organic sacrificial materials include resists and photoresists. The first sacrificial layer 830 is formed using methods known in the art, which will depend on the particular sacrificial material selected, and include spinning on, physical vapor deposition (PVD), sputtering, chemical vapor deposition (CVD), atomic layer deposition (ALD), and variants thereof. Typically, the first sacrificial material is selectively etchable relative to other materials exposed to the etchant in the finished device. In some preferred embodiments, the first sacrificial material, for example molybdenum, silicon, or tungsten, is etchable using XeF_2 .

[0064] In step 1130, a conductive layer 840' is formed over the first sacrificial layer 830, as illustrated in FIG. 8H. In embodiments in which the device is an interferometric modulator, the conductive layer is also referred to as a "reflective layer" or a "mirror layer." In some embodiments, the conductive layer 840' is a composite structure, comprising a plurality of sub-layers, which permits that optimization of various functions, for example, rigidity, mass, chemical resistance, etch resistance, and/or reflectivity. For example, in some embodiments, the reflective layer comprises, for example, a reflective surface sub-layer comprising aluminum, titanium, chromium, silver, and/or gold. Methods for forming the conductive layer 840' are known in the art, for example, PVD, CVD, ALD, and variants thereof.

[0065] In step 1140, the conductive layer 840' is patterned to form a movable conductor 840 as illustrated in FIG. 8I. As discussed above, in embodiments in which the device is an interferometric modulator, the movable conductor 840 is a movable mirror. In the illustrated embodiment, the first sacrificial layer 830 is not patterned in this step. In other

embodiments, first sacrificial layer 830 is patterned to form one or more openings in the first sacrificial material adjacent to the movable conductor 840.

[0066] In step 1150, a second sacrificial layer 850 is formed over the movable conductor 840 and the exposed portions of the first sacrificial layer 830, thereby providing the structure illustrated in FIG. 8J. The second sacrificial layer 850 comprises a second sacrificial material, which is independently selected from the same group of materials described above as being suitable for use as the first sacrificial material, and is formed using methods known in the art. In some preferred embodiments, the first and second sacrificial materials are selectively etchable by the same etchant, thereby permitting the removable of both the first 830 and second 850 sacrificial layers in a single release etch, as discussed in greater detail below.

[0067] In step 1160, a mask (not illustrated) is formed on the second sacrificial layer 850 by methods known in the art, for example, by photolithographic patterning. One or more first openings 866 in the second sacrificial layers 850 are formed using methods known in the art, for example, etching through the mask, to provide the structure illustrated in FIG. 8K. In the illustrated embodiment the first opening 866 in the second sacrificial layer is substantially centered over the movable conductor 840, which forms at least a portion of the bottom of the first opening 866. Other embodiments comprise a plurality of first openings 866. The illustrated embodiment also comprises second openings 852 through the first 830 and second 850 sacrificial layers, and adjacent to the movable conductor 840. In some embodiments, the first opening 866 and second opening(s) 852 are formed in the same step. In other embodiments, the first opening 866 and second opening(s) 852 are formed in separate steps.

[0068] In step 1170, the first component 874 of the composite connector (872 in FIG. 8A) is formed in the first opening 866 in the second sacrificial material from a filler material to provide the structure illustrated in FIG. 8L. In the illustrated embodiment, the filler material, and consequently, the first component 874, substantially covers the side walls 868 of the first opening (FIG. 8K), but does not entirely cover the bottom 869 of the first opening 866. In some embodiments, the filler material does not entirely cover the side walls 868 of the first opening; that is, the thickness of the filler material is less than the height of

the opening 866, thereby providing, for example, the first component 874 illustrated in FIG. 8E. Returning to FIG. 8L, the filler material also substantially fills the second opening(s) 852 to form support post plugs 892. In the illustrated embodiment, the first component 874 of the composite connector and the support post plugs 892 comprise the same filler material. Those skilled in the art will understand that in other embodiments, the first component 874 of the composite connector and the support post plugs 892 do not comprise the same filler material. As will be discussed in greater detail below, in some preferred embodiments, the filler material is deposited in a spin-on process.

[0069] As used herein, the term "filler material" refers to a material: (1) that provides a surface over which another layer with predetermined properties, for example, adhesion, thickness, physical integrity, and/or electrical integrity, is formed, for example, by filling a step, ledge, and/or discontinuity in the fabrication of a device; and/or (2) that fills an opening to provide a component with predetermined properties in a finished device. Examples of the predetermined properties include, for example, adhesion, physical integrity, and/or electrical conductivity. In some embodiments described herein, the filler material performs both of these functions. In some embodiments, the filler material performs additional functions. Suitable filler materials are known in the art. Those skilled in the art will understand that selecting an appropriate filler material depends on factors including the particular application, the particular materials used, as well as the particular function(s) of the filler material.

[0070] Those skilled in the art will understand that, under certain circumstances, forming a layer with the desired properties over some substrates is relatively difficult. For example, forming a deformable layer 1270 over the structure illustrated in FIG. 8L can result in non-uniformities, for example, breaks 1278 or thin portions 1280, in the deformable layer 1270 as illustrated in FIG. 12A. In the illustrated embodiment, the non-uniformities form around discontinuities in the underlying layer. In the illustrated embodiment, the discontinuities include transitions between a surface and an opening 1282, transitions between the wall of an opening and the bottom of an opening 1284, and reentrant regions 1286. Those skilled in the art will understand that certain types of layers are also difficult to form over other types of features, for example, steep, rough, and/or irregular surfaces.

[0071] With reference to FIG. 12A, in some embodiments, the filler material facilitates forming a layer over such a substrate by filling or covering at least some of the discontinuities in the substrate. In some embodiments, the filler material of the first component 1274 of the connector and/or support post 1290 forms a contact angle θ that is greater than 0° (*i.e.*, non-reentrant), more preferably, greater than about 10° , as illustrated in FIG. 12B.

[0072] In some preferred embodiments, the filler material comprises a self-planarizing material, for example, a resist, a photoresist, a spin-on glass (SOG), or a spin-on dielectric (SOD). In other embodiments, the filler material comprises another material, for example, a planarizing material, a polymer, and/or a conformal coating. As used herein, the term "self-planarizing" is used in its usual meaning, and in particular, to refer to materials that, when applied to a surface, tend to fill and/or cover openings, irregularities, and/or features on the surface, thereby providing a smoother exposed surface. Those skilled in the art will understand that the surface formed by a self-planarizing material does not necessarily define a plane. Suitable photoresists include positive resists and negative resists, including epoxy, polyimide, polyacrylate, i-line, g-line, 193 nm, deep-UV, and/or thick-film resists. Exemplary commercially available photoresists include SU-8 (MicroChem, Inc., Newton, MA), SPR3600 (Shipley, Marlborough, MA), SPR995-CM (Shipley), Ultra-i-123 (Shipley), AZ-9200 (Clariant, Muttenz, Switzerland), P4000 (Clariant), AZ MiR 700 (Clariant), AZ 7900 (Clariant), AZ5200 (Clariant), AZ DX (Clariant), and NR-7 (Futurex). Methods for applying self-planarizing materials are well known in the art, for example, spin coating. In some embodiments, the photoresist is photopatterned. In some embodiments, the photoresist is photopatterned by irradiation through the substrate 810, *i.e.*, from the bottom of the device 800 as viewed in FIG. 8A. In some embodiments, the irradiation comes from above the device 800 as viewed in FIG. 8A. In some embodiments, the photoresist is irradiated from both sides. In some embodiments a second photoresist is applied to the filler material and photopatterned in order to pattern the filler material.

[0073] The properties of the self-planarizing material are controlled by methods known in the art. For example, in the application of a spin-on material, factors including spin speed and dilution affect the thickness of the film of spin-on material as well as the height of

its features. In some embodiments, the spin speed affects the thickness of a lip 878 of the first component (FIG. 8L), while maintaining a thinner layer of resist in the opening. Other factors affecting the properties of the self-planarizing material include the bake history, for example, before and after photopatterning. For example, baking tends to shrink a photoresist. Some embodiments include a plasma descum step. Both the bake history and plasma descum affect the profile and height of the resist. In some embodiments, the plasma descum removes resist from the bottom 869 of the first opening 866 and/or second opening 852 after forming the first component of the connector and/or support post (874 and 894, respectively). As discussed above, exposing the movable conductor 840 on the bottom 869 of the first opening 866 is useful in some embodiments of the disclosed device in which the first component 874 of the connector is not electrically conductive. In some embodiments, the plasma descum also improves the adhesion of layers deposited on the self-planarizing material (for example, the first component 874), possibly by roughening the surface of the resist.

[0074] Other suitable filler materials include dielectric materials of any type known in the art, for example, metal oxides, nitrides and/or carbides. Examples of suitable dielectric materials include silicon oxide, silicon nitride, silicon carbide, fluorinated silica glass, organosilicate glass, aluminum oxide, and combinations thereof. Other dielectrics known in the art are also suitable. Another suitable filler material is a metal, for example, aluminum, copper, gold, tungsten, nickel, titanium, and the like, and alloys or mixtures thereof. Another suitable filler material is silicon, either epitaxial, polycrystalline, or amorphous. Methods for depositing such filler materials are known in the art, for example, CVD, PVD, ALD, electroplating, evaporation, sputtering, and lift off. A preferred method for depositing the filler material is spinning on, which reduces or eliminates the need for a directional or "spacer" etch to expose the movable conductor or mirror 840 (FIG. 8L) at bottom 869 of the first opening 866.

[0075] In step 1180, the deformable layer 870 is formed over the structure illustrated in FIG. 8L using methods known in the art to provide the structure illustrated in FIG. 8M. In the illustrated embodiment, the second component 876 of the connector is integrally formed with the deformable layer 870.

[0076] In step 1190, the first sacrificial layer 830 and the second sacrificial layer 850 are removed and/or etched away to open the cavities above and below the movable conductor or mirror 840, to provide the structure illustrated in FIG. 8A. In some embodiments, the first 830 and second 850 sacrificial layers are removed in a sacrificial or "release etch." The first 830 and the second 850 sacrificial layers are removed either in separate processes or in a single process. Those skilled in the art will understand that the particular etching conditions depend on the identity of the first and second sacrificial materials. In some embodiments, the one or both of the sacrificial materials are selectively removed relative to other structures in the device, for example, the structures illustrated in FIG. 8A. In some preferred embodiments, one or both of the first and second sacrificial materials is selectively etchable using a gas phase etchant (e.g., XeF_2).

[0077] Method 1100 is also useful for fabricating the MEMS device illustrated in FIG. 9A. Steps 1110–1150 are substantially as described above, and as illustrated in FIG. 8F–FIG. 8J. In step 1160, at least one first opening 966 and one or more second openings 952 are formed in a second sacrificial layer 950 and first sacrificial layer 930 to provide the structure illustrated in FIG. 9B. Viewed from the top (FIG. 9C), the first opening 966 is annular, defining a portion 976 of the second sacrificial layer, which forms the second component of the connector 972 (FIG. 9A). For example, in some embodiments, the first opening 966 is a circle as illustrated in FIG. 9C. In other embodiments, the first opening 966 has another shape, for example, a square, rectangle, hexagon, an ellipse, or another shape. In some embodiments, the first opening 966 is not annular. In some of these embodiments, the release etch described above etches away the portion 976 of the second sacrificial layer in step 1190. In some of these embodiments, the first component 974 of the connector electrically connects the movable conductor 940 to the deformable layer 970 (FIG. 9A), and consequently, the filler material is electrically conductive.

[0078] In step 1170, a first component 974 of the connector is formed from a filler material to provide the structure illustrated in FIG. 9D. In the illustrated embodiment, the filler material substantially fills the first opening 966 in the second sacrificial layer 950 to form the first component 974. In other embodiments, the filler material does not substantially fill the first opening 966, thereby providing, for example, a first component 974

as illustrated in FIG. 9E. Returning to FIG. 9D, in the illustrated embodiment, support plug posts 992 are also formed in this step, as described above. The filler material and method of application are substantially as described above.

[0079] In step 1180, the deformable layer 1070 is formed as discussed above to provide the structure illustrated in FIG. 9F. In step 1190, the first and second sacrificial layers 830 and 850 are removed as discussed above to provide the structure illustrated in FIG. 9A. As best seen in FIG. 9F, in embodiments in which first component 974 of the connector forms a closed shape, the movable mirror 940, deformable layer 970, and first component 974 of the connector, together encase a piece 976 of the second sacrificial material, thereby preventing its etching and forming the second component 976 of the connector.

[0080] As discussed above, in some embodiments, at least one of the first component 974 and second component 976 is electrically conductive. In some preferred embodiments, the second component 976 comprises an electrically conductive sacrificial material, for example molybdenum or tungsten.

[0081] Method 1100 also provides a method for fabricating the apparatus illustrated in FIG. 10A. Steps 1110–1160 are substantially as described above, and as illustrated in FIG. 8F–FIG. 8K. In step 1170, a first component 1094 of the support post and a first component 1074 of the connector are simultaneously formed from a filler material as discussed above to provide the structure illustrated in FIG. 10C. In step 1180, a deformable layer 1070 is formed, which forms the second component 1096 of the support post, as illustrated in FIG. 10D, as well as the second component 1076 of the connector. In step 1190, the first and second sacrificial layers 1030 and 1050 are removed to form the structure illustrated in FIG. 10A.

[0082] Those skilled in the art will understand that changes in the apparatus and manufacturing process described above are possible, for example, adding and/or removing components and/or steps, and/or changing their orders. Moreover, the methods, structures, and systems described herein are useful for fabricating other electronic devices, including other types of MEMS devices, for example, other types of optical modulators.

[0083] Moreover, while the above detailed description has shown, described, and pointed out novel features of the invention as applied to various embodiments, it will be understood that various omissions, substitutions, and changes in the form and details of the device or process illustrated may be made by those skilled in the art without departing from the spirit of the invention. As will be recognized, the present invention may be embodied within a form that does not provide all of the features and benefits set forth herein, as some features may be used or practiced separately from others.

WHAT IS CLAIMED IS:

1. A microelectromechanical systems device comprising:
 - a substrate;
 - a deformable layer;
 - a support structure supporting the deformable layer;
 - a movable conductor positioned between the substrate and the deformable layer; and
 - a connector securing the movable conductor to the deformable layer;wherein
 - at least one of the connector and the support structure comprises a first component and a second component,
 - at least a portion of the first component is disposed on the perimeter of at least one of the connector and the support structure; and
 - the first component comprises an electrically insulating filler material.
2. The microelectromechanical systems device of claim 1, wherein the support structure comprises a plurality of support posts, wherein the support posts are supported by the substrate and support the deformable layer.
3. The microelectromechanical systems device of claim 1, wherein the filler material comprises a self-planarizing material.
4. The microelectromechanical systems device of claim 1, wherein the filler material comprises a material selected from the group consisting of a dielectric material, a metal, and silicon.
5. The microelectromechanical systems device of claim 1, wherein the connector and deformable layer are integrated.
6. The microelectromechanical systems device of claim 1, wherein the connector comprises a first component and a second component, and the first component is annular, forming the sides of at least a portion of the connector.
7. The microelectromechanical systems device of claim 6, wherein the first component forms the sides of the entire connector.

8. The microelectromechanical systems device of claim 7, wherein the second component comprises a sacrificial material.
9. The microelectromechanical systems device of claim 8, wherein the sacrificial material comprises molybdenum, silicon, or a combination thereof.
10. The microelectromechanical systems device of claim 1, wherein at least one support post comprises a support post plug substantially formed from filler material.
11. The microelectromechanical systems device of claim 1, wherein the microelectromechanical systems device is an optical modulator.
12. The microelectromechanical systems device of claim 1, wherein:
the connector comprises a first component, and
the first component contacts the movable conductor and forms the sides of the lower portion of the connector.
13. The microelectromechanical systems device of claim 12, wherein the second component comprises a conductor.
14. The microelectromechanical systems device of claim 1, wherein the filler material is a spin-on material.
15. The microelectromechanical systems device of claim 1, further comprising:
a processor that is in electrical communication with at least said movable conductor, said processor being configured to process image data;
a memory device in electrical communication with said processor.
16. The microelectromechanical systems device of claim 15, further comprising:
a driver circuit configured to send at least one signal to said display.
17. The microelectromechanical systems device of claim 16, further comprising:
a controller configured to send at least a portion of said image data to said driver circuit.
18. The microelectromechanical systems device of claim 15, further comprising:
an image source module configured to send said image data to said processor.
19. The microelectromechanical systems device of claim 18, wherein said image source module comprises at least one of a receiver, transceiver, and transmitter.
20. The microelectromechanical systems device of claim 15, further comprising:

an input device configured to receive input data and to communicate said input data to said processor..

21. A method for fabricating an optical modulator comprising:

forming over a substrate, a layer of a first sacrificial material, a mirror, and a layer of a second sacrificial material;

forming a first opening through the layer of the second sacrificial material thereby exposing the mirror; and

filling at least a portion of the sides of the opening with a filler material.

22. The method of claim 21, wherein the first opening is substantially centered over the mirror.

23. The method of claim 21, further comprising:

forming a second opening through the layer of the second sacrificial material and the first sacrificial material, adjacent to the mirror;

filling, at least partially, the second opening with a filler material; and

forming a deformable layer over the filler material.

24. The method of claim 22, wherein the second opening is substantially completely filled with the filler material.

25. The method of claim 21, wherein the filling comprises spin coating the filler material.

26. The method of claim 25, wherein the filler material comprises a photosensitive polymer.

27. The method of claim 26, wherein the filler material comprises a photoresist.

28. The method of claim 25, wherein the filler material comprises a spin-on glass or a spin-on dielectric.

29. The method of claim 28, wherein the filling comprises depositing the filler material to a thickness less than a height of the opening.

30. The method of claim 21, wherein the first opening is annular.

31. The method of claim 30, wherein the first opening is substantially filled with the filler material.

32. An interferometric modulator fabricated by the method of any of claims 21–31.
33. A microelectromechanical systems device comprising:
 - a deformable conductive layer;
 - a movable conductive layer;
 - an electrically conductive core extending between the deformable conductive layer and the movable conductive layer; and
 - a layer of an electrically insulating conductive material surrounding the conductive core.
34. The microelectromechanical systems device of claim 33, wherein:
 - the microelectromechanical systems device is an optical modulator; and
 - the movable conductive layer is a mirror.
35. A microelectromechanical systems device comprising:
 - a substrate;
 - a layer of a first sacrificial material formed over the substrate;
 - a conductor formed over the layer of the first sacrificial material;
 - a layer of a second sacrificial material formed over the conductor;
 - a first opening through the layer of the second sacrificial material, wherein the first opening exposes the conductor; and
 - a means for filling discontinuities in first opening with a filler material.
36. The microelectromechanical systems device of claim 35, further comprising:
 - a deformable layer formed over the layer of the second sacrificial material; and
 - a plurality of posts extending between the substrate and the deformable layer.
37. A microelectromechanical systems device comprising:
 - a movable means for actuating the device;
 - a support means for supporting the movable means;
 - a conductive means for communicating electrical signals between the movable means and the means for supporting the movable means; and

a filler means for facilitating formation of the means for communicating electrical signals.

38. The microelectromechanical systems device of claim 37, wherein the movable means is a movable conductor.

39. The microelectromechanical systems device of claim 37 or claim 38, wherein the support means comprises a plurality of support posts.

40. The microelectromechanical systems device of any of claims 37-39, wherein the conductive means is a second component of a connector comprising an electrically conductive material.

41. The microelectromechanical systems device of any of claims 37-40, wherein the filler means is a first component of a connector comprising a filler material.

42. A method for operating a microelectromechanical systems device, wherein the microelectromechanical systems device comprises:

a compartment;

a deformable conductive layer;

a movable conductive layer, wherein the movable conductive layer is movable between a first position and a second position in the compartment;

an electrically conductive core extending between the deformable conductive layer and the movable conductive layer; and

a layer of a electrically insulating material surrounding the conductive core,

the method comprising applying a first voltage to the movable conductive layer sufficient to move the movable conductive layer from the first position to the second position.

43. The method of claim 42, wherein

the microelectromechanical systems device is an interferometric modulator,

the movable conductive layer is a movable mirror, further comprising a reflective surface,

the first position is a relaxed position, and

the second position is an actuated position.

44. The method of claim 42, wherein the first voltage is about +5 volts.

45. The method of claim 42, further comprising applying a second voltage to the movable conductive layer sufficient to move the conductive layer from the second position to the first position.

46. The method of claim 45, wherein the second voltage is about -5 volts.

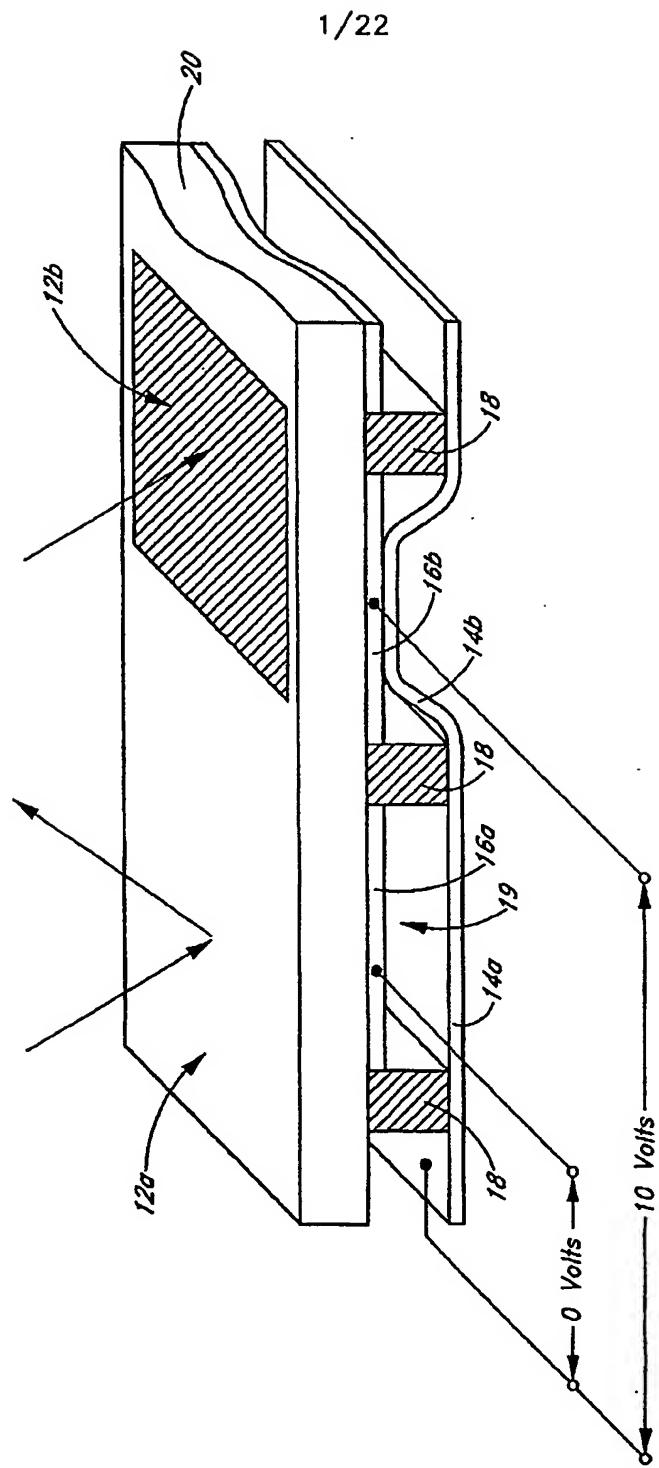


FIG. 1

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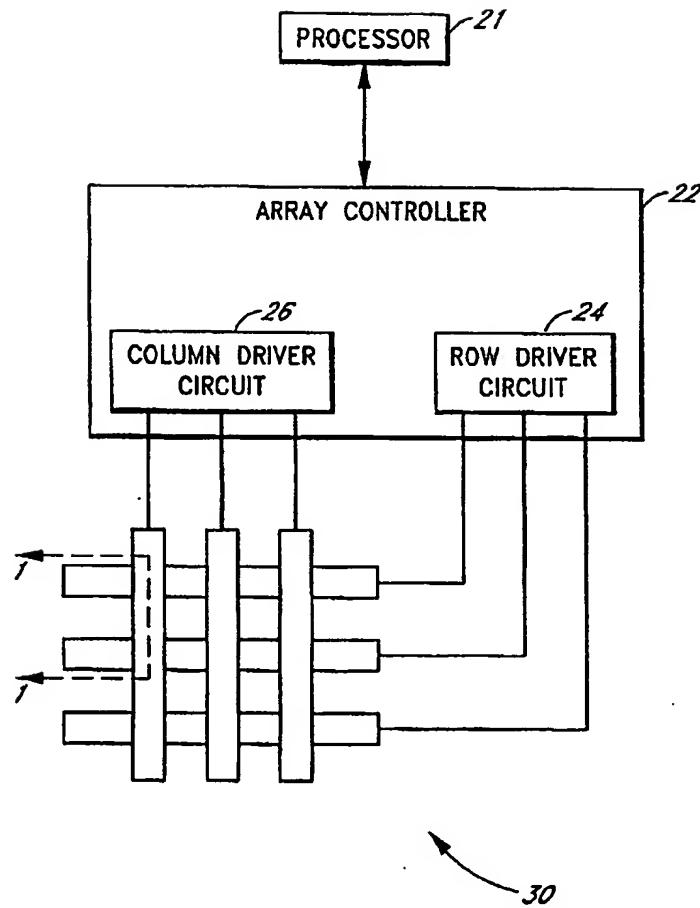


FIG. 2

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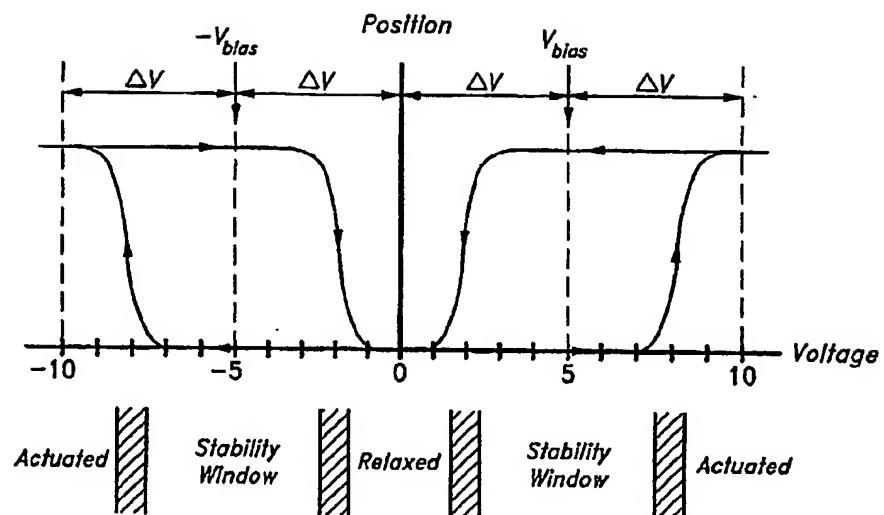


FIG. 3

Column Output Signals			
Row Output Signals	$+V_{bias}$	$-V_{bias}$	
	0	Stable	Stable
	$+\Delta V$	Relax	Actuate
	$-\Delta V$	Actuate	Relax

FIG. 4

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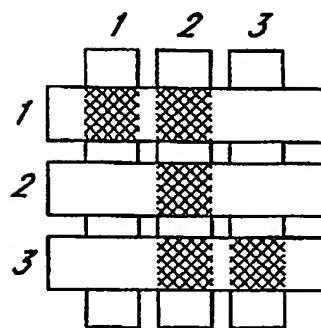


FIG. 5A

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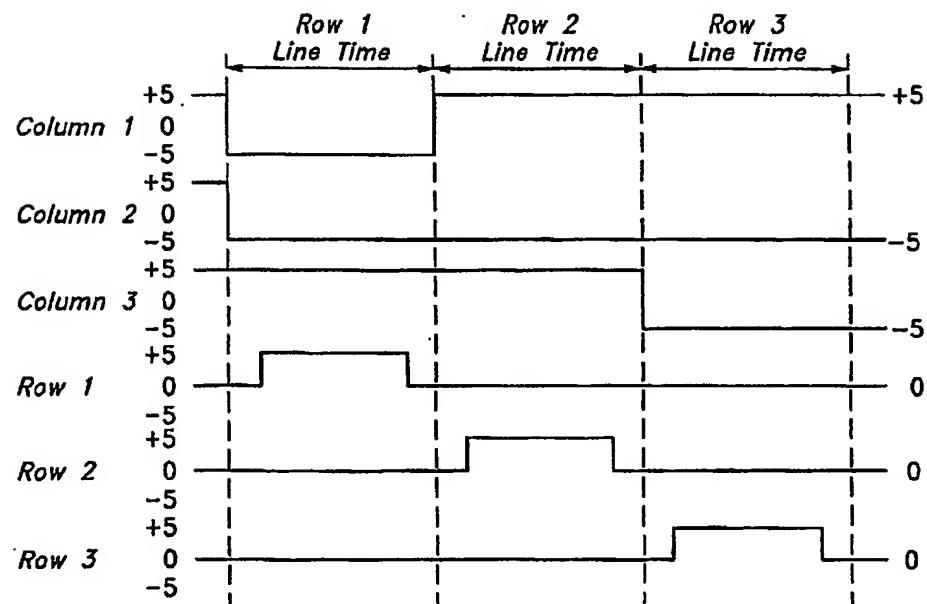


FIG. 5B

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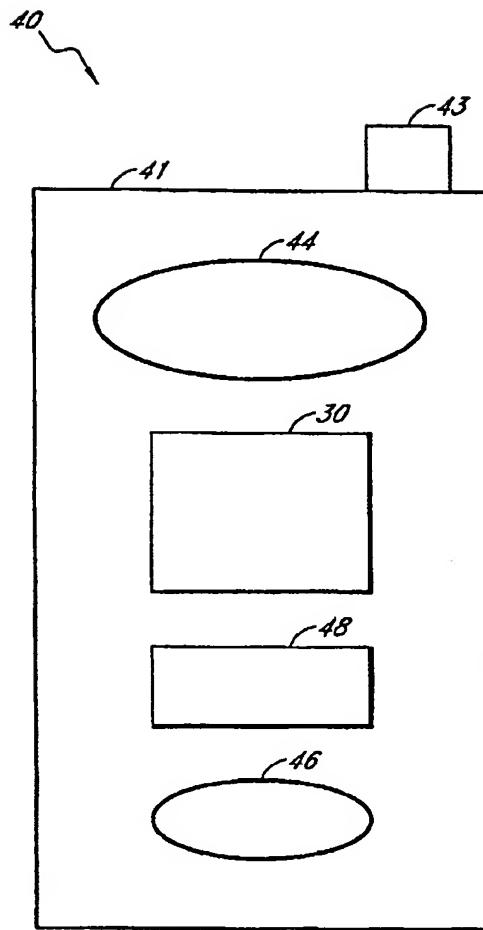
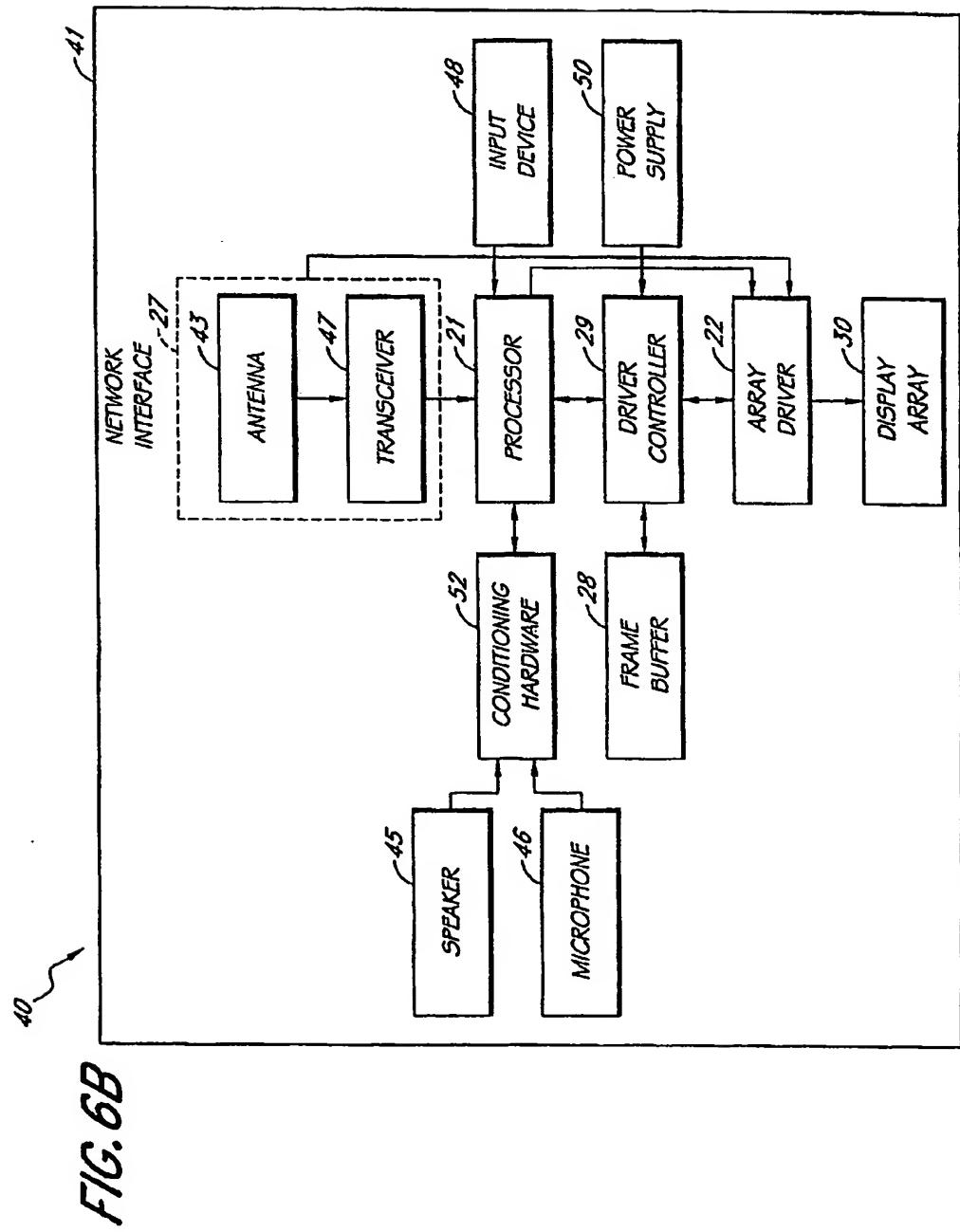


FIG. 6A

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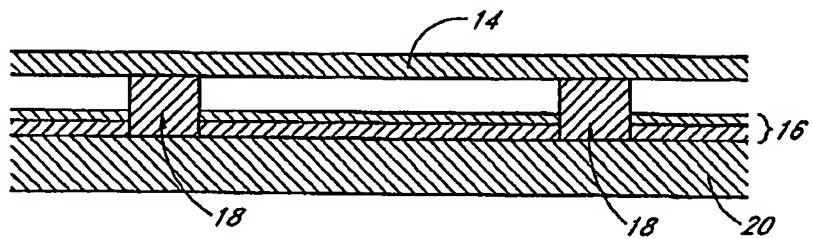


FIG. 7A

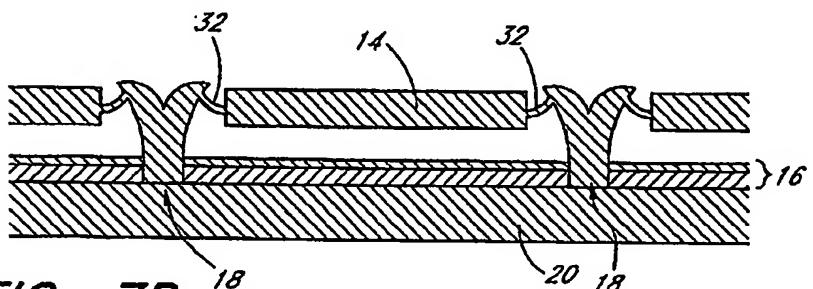


FIG. 7B

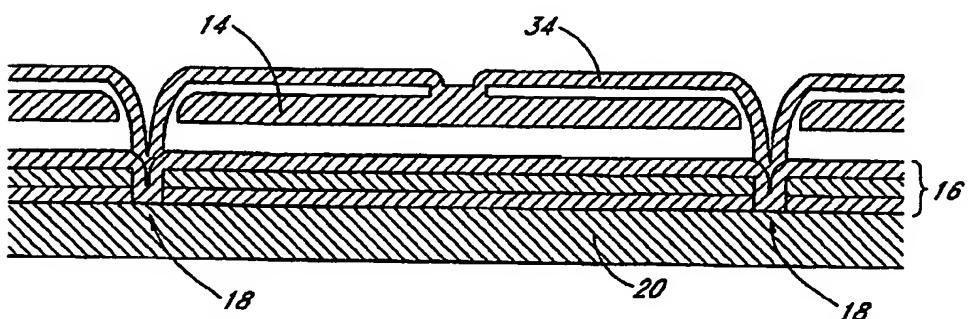


FIG. 7C

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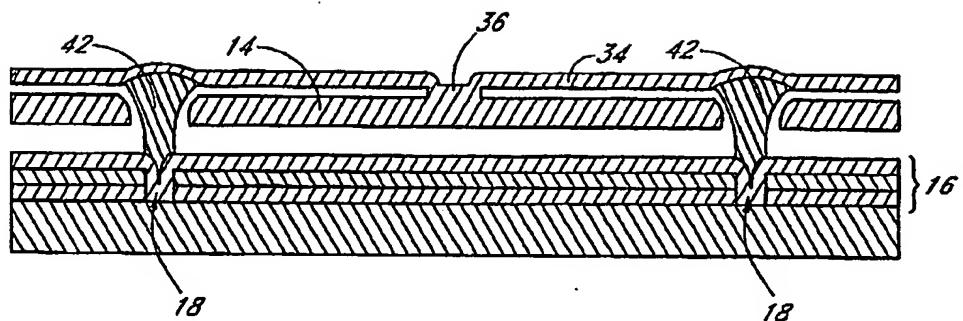


FIG. 7D

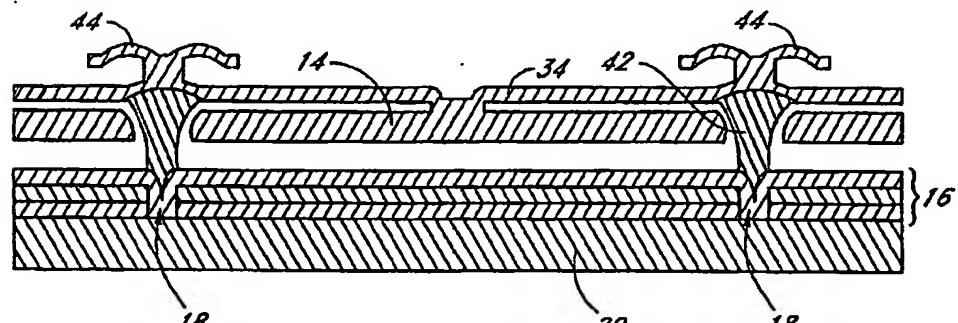


FIG. 7E

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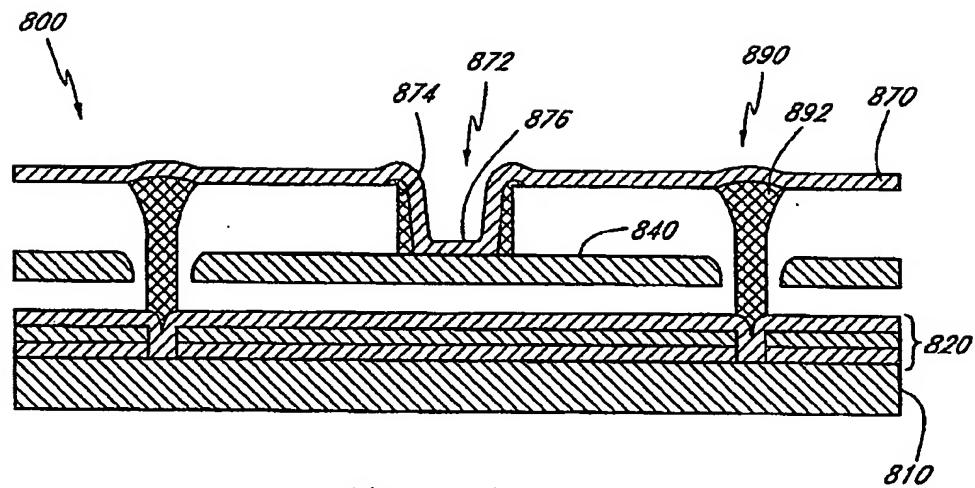
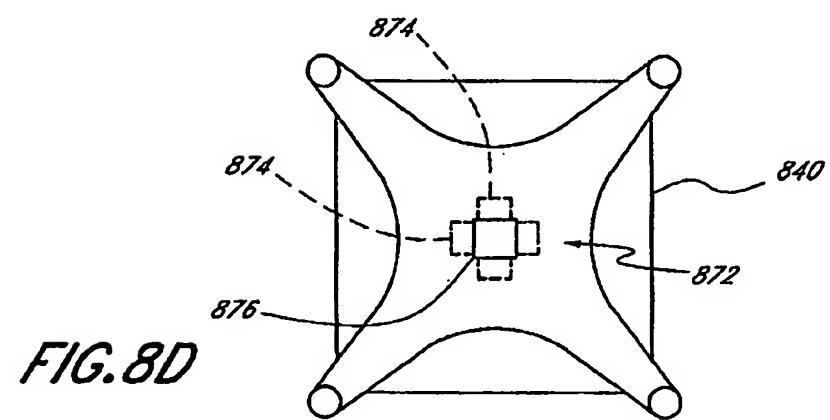
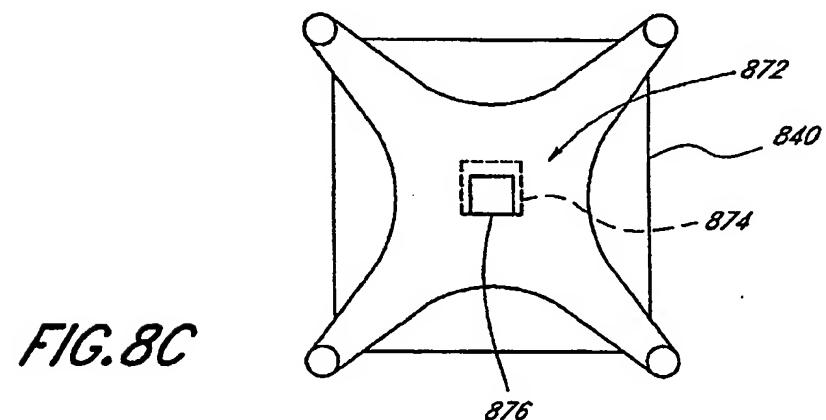
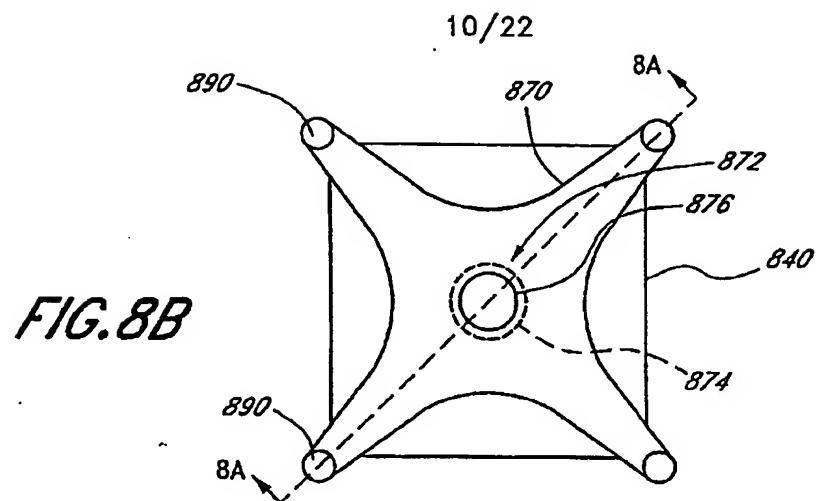


FIG. 8A



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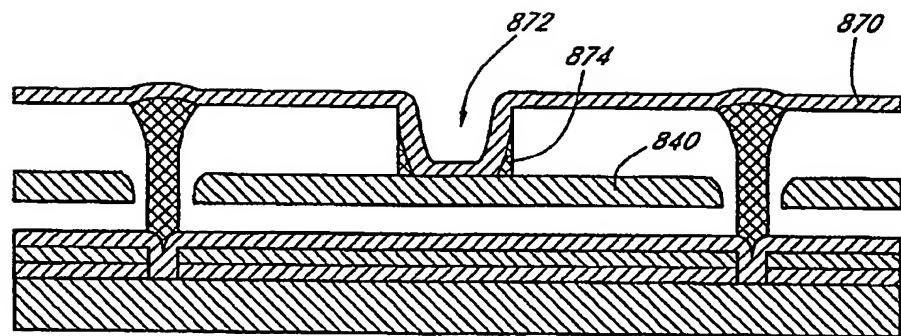


FIG. 8E

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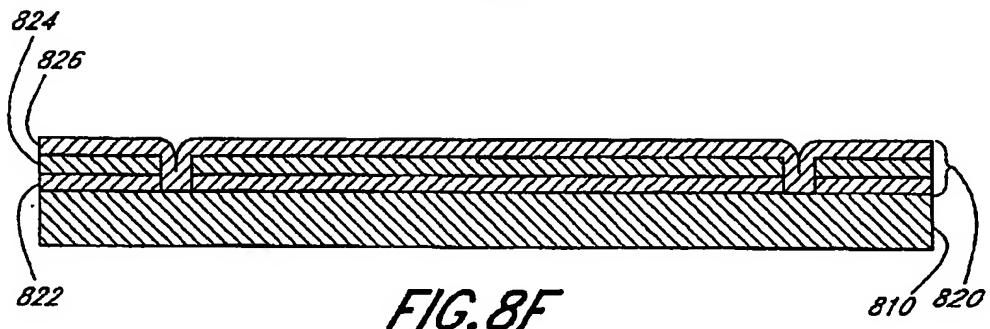


FIG. 8F

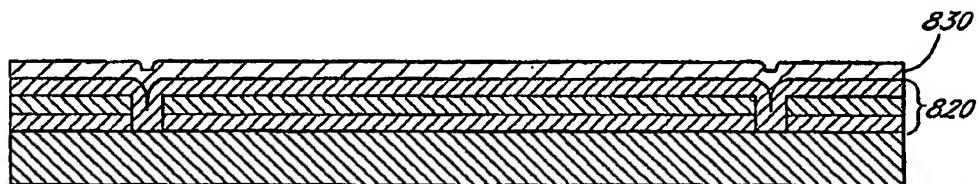


FIG. 8G

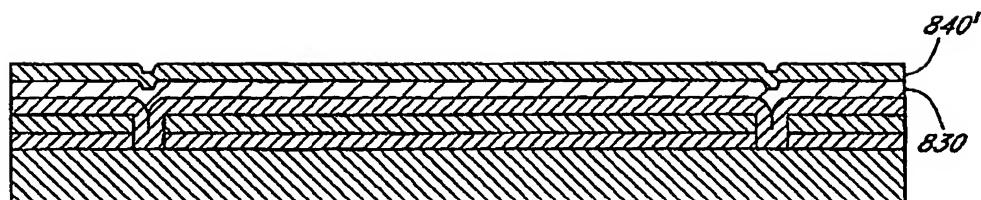


FIG. 8H

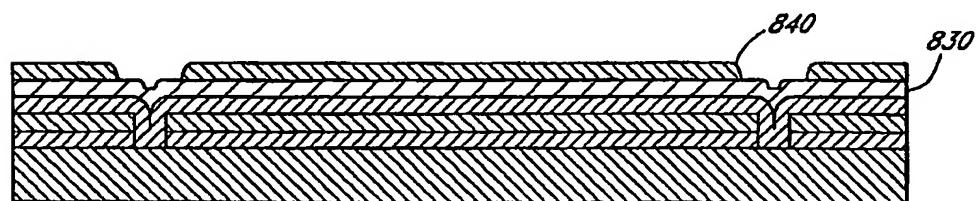


FIG. 8I

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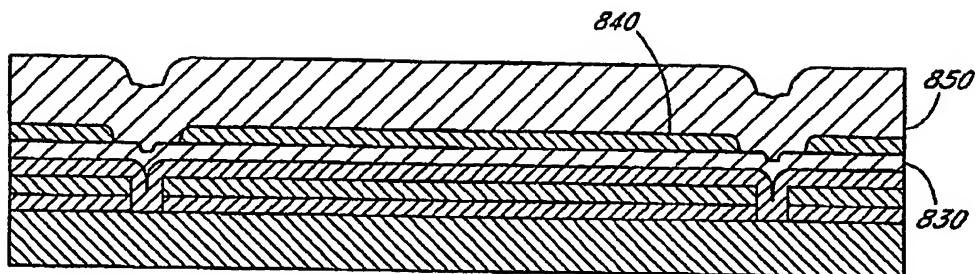


FIG. 8J

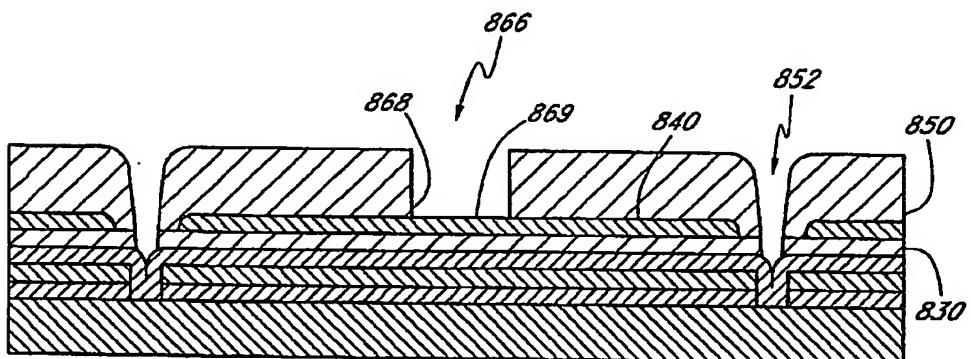


FIG. 8K

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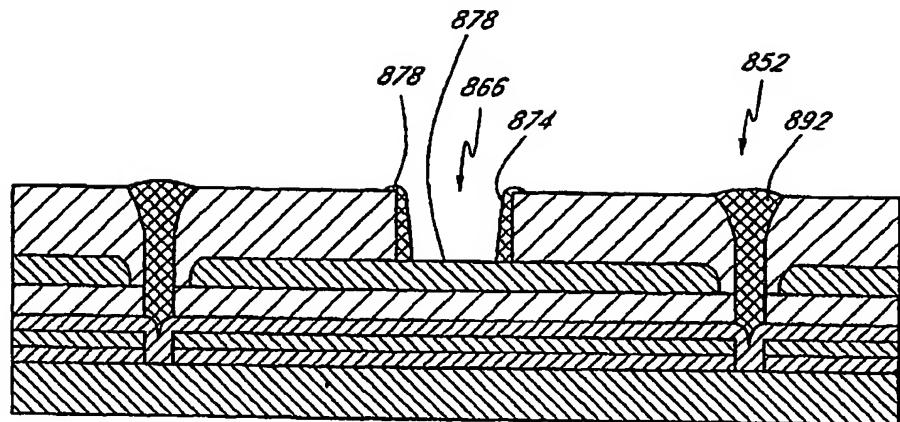


FIG. 8L

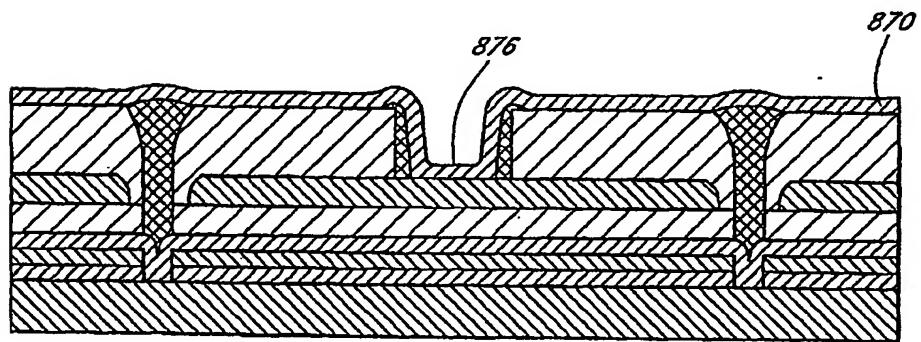


FIG. 8M

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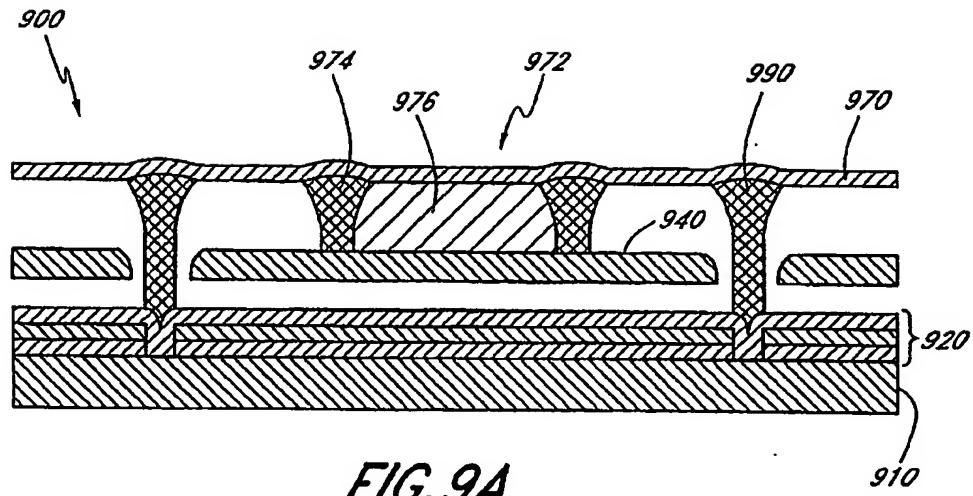


FIG. 9A

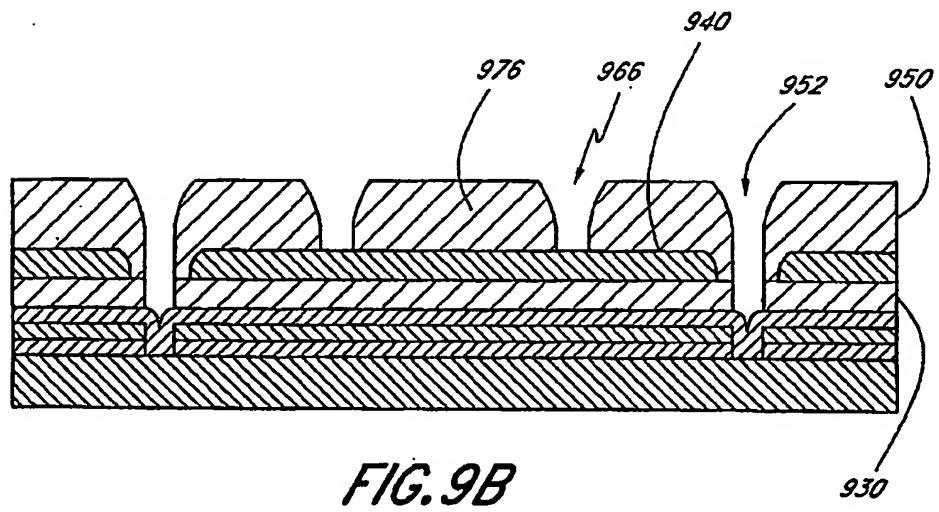


FIG. 9B

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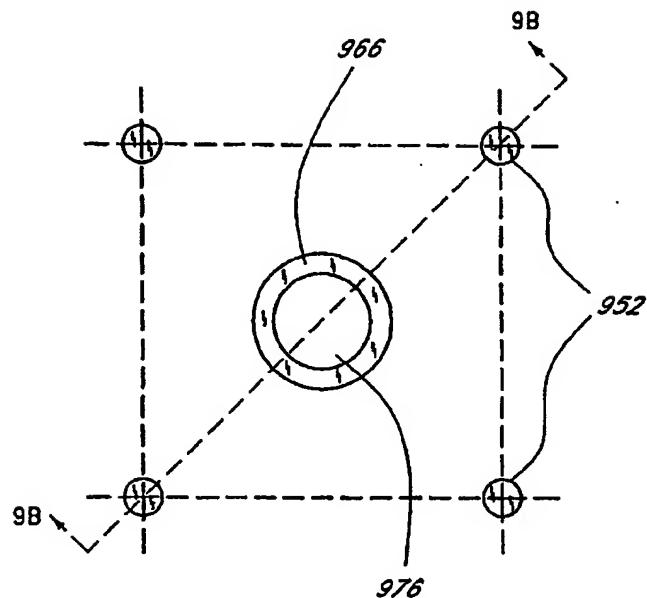


FIG. 9C

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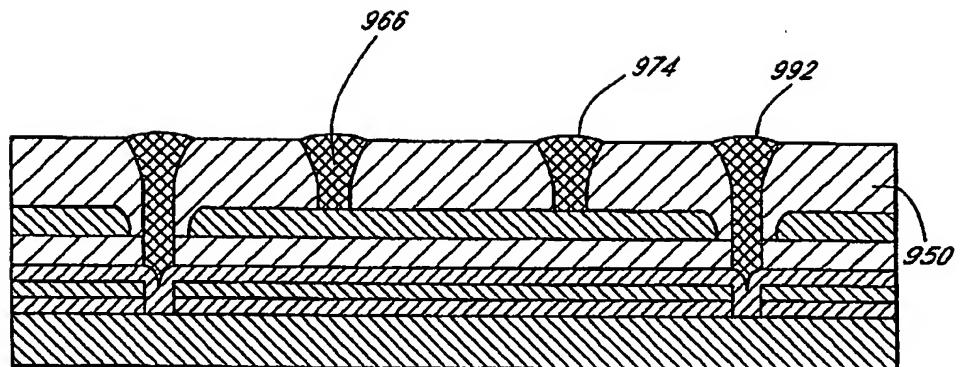


FIG. 9D

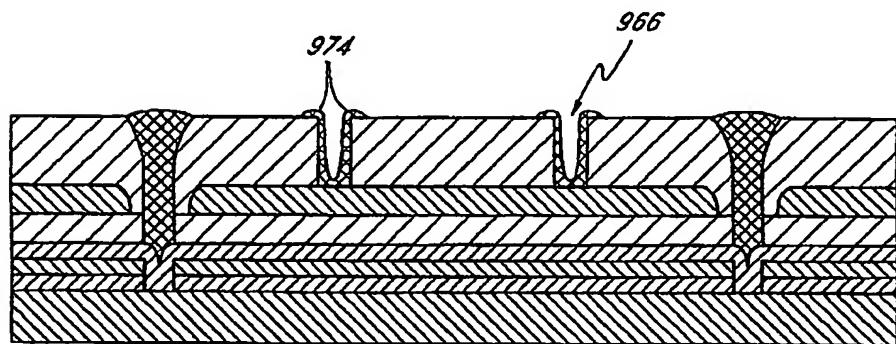


FIG. 9E

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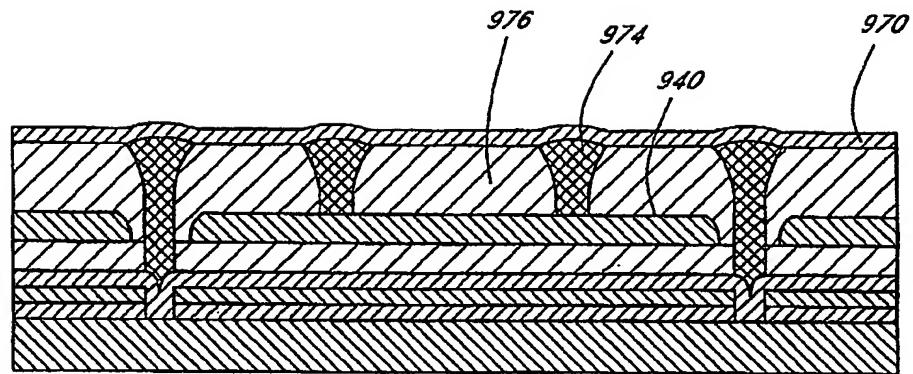


FIG. 9F

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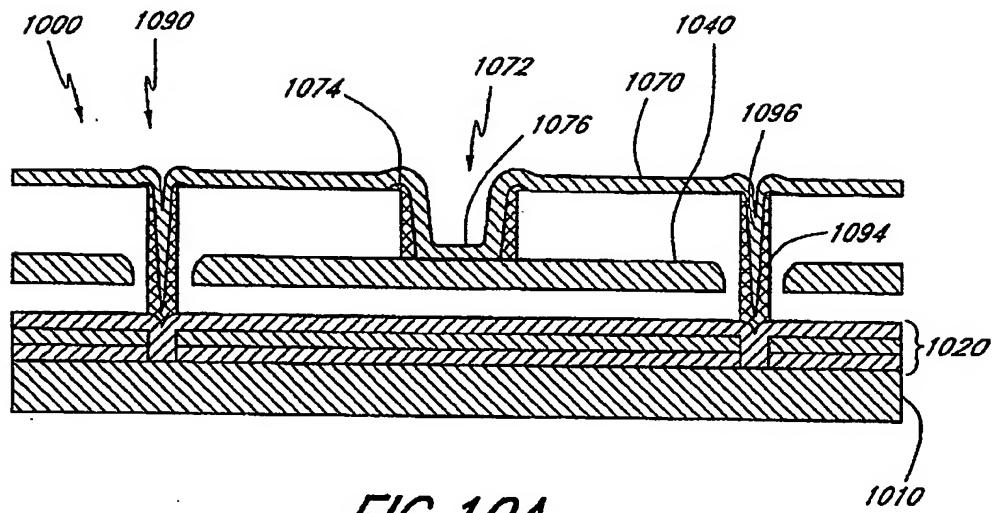


FIG. 10A

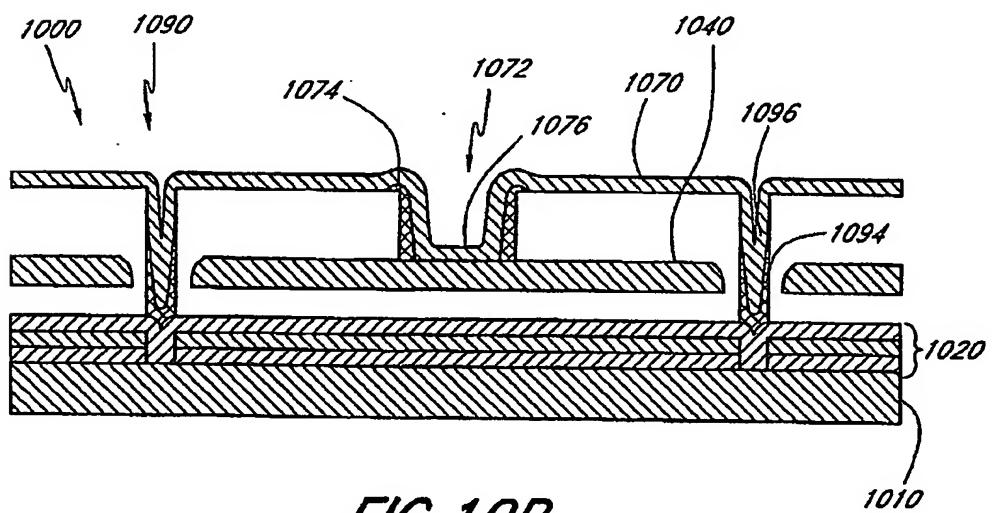


FIG. 10B

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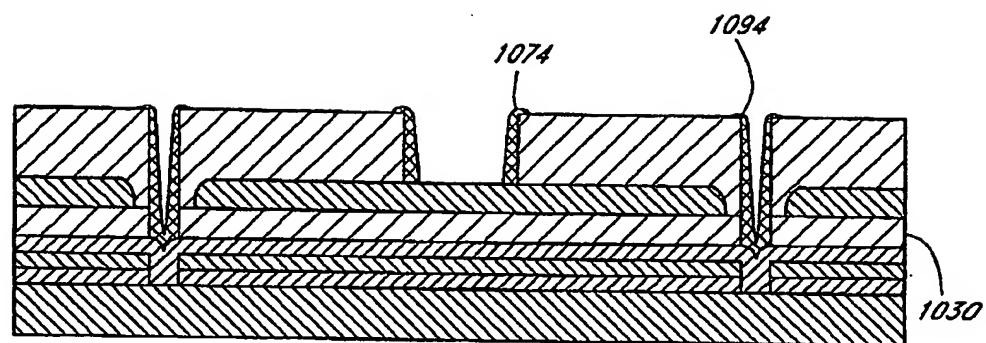


FIG. 10C

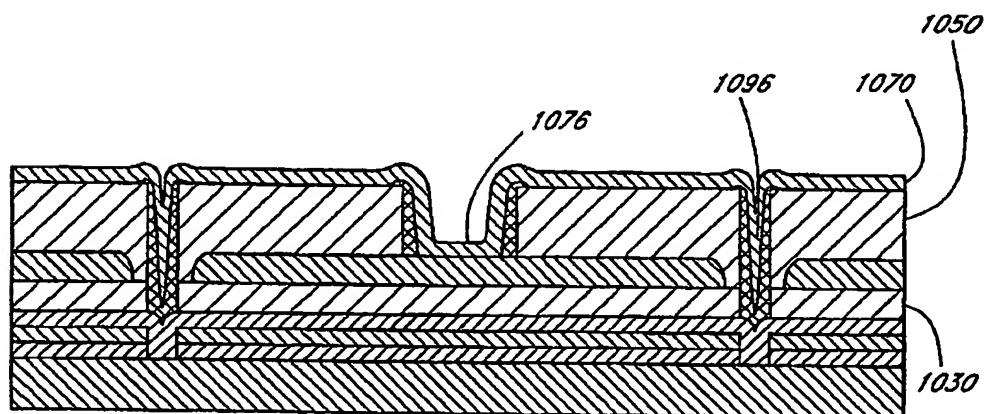


FIG. 10D

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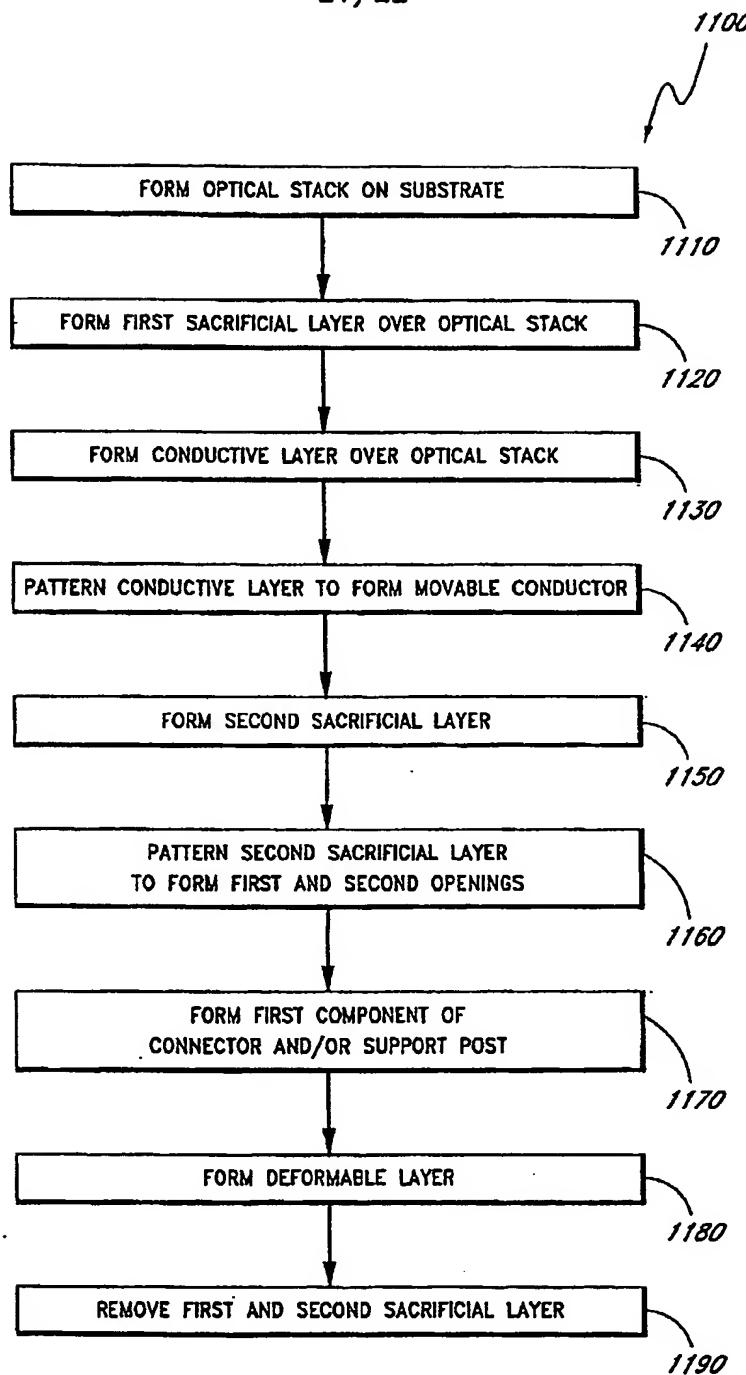


FIG. 11

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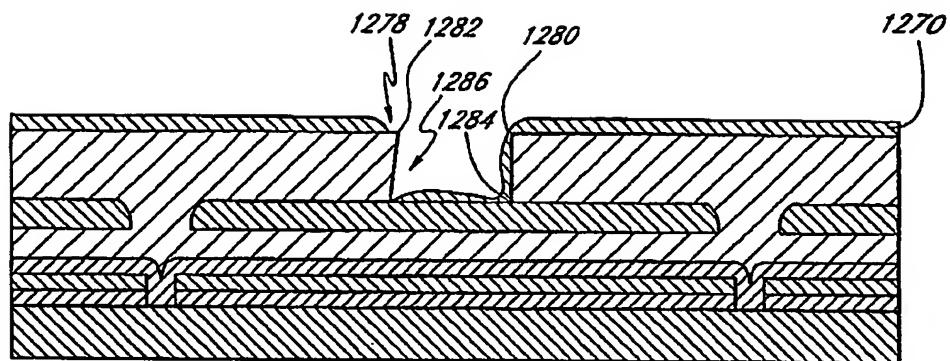


FIG. 12A

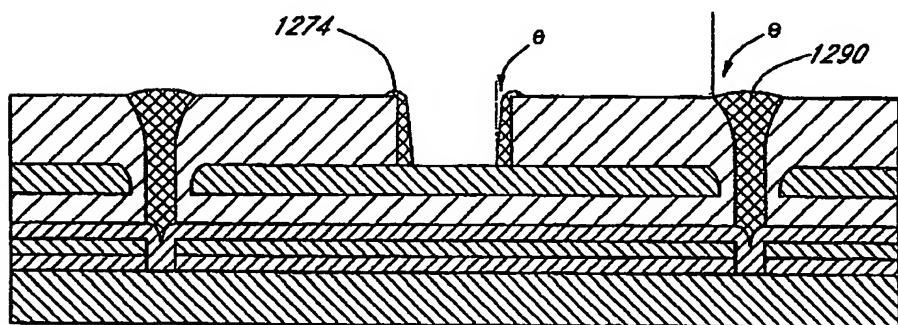


FIG. 12B

INTERNATIONAL SEARCH REPORT

International Application No
PCT /US2005/032647

A. CLASSIFICATION OF SUBJECT MATTER B81B3/00 G02B26/08		
According to International Patent Classification (IPC) or to both national classification and IPC		
B. FIELDS SEARCHED Minimum documentation searched (classification system followed by classification symbols) B81B G02B		
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched		
Electronic data base consulted during the international search (name of data base and, where practical, search terms used) EPO-Internal, INSPEC		
C. DOCUMENTS CONSIDERED TO BE RELEVANT		
Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US 2004/051929 A1 (SAMPSELL JEFFREY BRIAN ET AL) 18 March 2004 (2004-03-18) figures 3-5, 6a-7f, 9a-9f paragraph '0023! - paragraph '0039!	1-5, 10-14, 25-28
X	paragraph '0041! - paragraph '0044!	21-24, 32, 35-41
Y	US 2002/126364 A1 (MILES MARK W) 12 September 2002 (2002-09-12) paragraph '0141! - paragraph '0144! figures 9, 28B	15-20, 29, 42-46
Y	EP 0 694 801 A (TEXAS INSTRUMENTS INCORPORATED) 31 January 1996 (1996-01-31) figure 12 column 5, line 5 - column 7, line 15	15-20 29, 42-46
<input type="checkbox"/> Further documents are listed in the continuation of box C.		<input checked="" type="checkbox"/> Patent family members are listed in annex.
<p>* Special categories of cited documents:</p> <p>*'A' document defining the general state of the art which is not considered to be of particular relevance</p> <p>*'E' earlier document but published on or after the international filing date</p> <p>*'L' document which may throw doubts on priority, claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)</p> <p>*'O' document referring to an oral disclosure, use, exhibition or other means</p> <p>*'P' document published prior to the international filing date but later than the priority date claimed</p> <p>*'T' later document published after the International filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention</p> <p>*'X' document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone</p> <p>*'Y' document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.</p> <p>*'&' document member of the same patent family</p>		
Data of the actual completion of the International search	Data of mailing of the International search report	
13 December 2005	28/12/2005	
Name and mailing address of the ISA European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl. Fax. (+31-70) 340-3016	Authorized officer Meister, M	

INTERNATIONAL SEARCH REPORTInternational application No.
PCT/US2005/032647**Box II Observations where certain claims were found unsearchable (Continuation of Item 2 of first sheet)**

This International Search Report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:

1. Claims Nos.: because they relate to subject matter not required to be searched by this Authority, namely:

2. Claims Nos.: 33, 34 because they relate to parts of the International Application that do not comply with the prescribed requirements to such an extent that no meaningful International Search can be carried out, specifically:
see FURTHER INFORMATION sheet PCT/ISA/210

3. Claims Nos.: because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).

Box III Observations where unity of invention is lacking (Continuation of Item 3 of first sheet)

This International Searching Authority found multiple inventions in this international application, as follows:

1. As all required additional search fees were timely paid by the applicant, this International Search Report covers all searchable claims.

2. As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.

3. As only some of the required additional search fees were timely paid by the applicant, this International Search Report covers only those claims for which fees were paid, specifically claims Nos.:

4. No required additional search fees were timely paid by the applicant. Consequently, this International Search Report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.:

Remark on Protest

The additional search fees were accompanied by the applicant's protest.
 No protest accompanied the payment of additional search fees.

FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

Continuation of Box II.2

Claims Nos.: 33, 34

The subject-matter of claim 33 is in particular characterised by the layer which is mentioned last. This layer is claimed to be "of an electrically insulating conductive material". This, however, is an unresolvable contradiction since an insulator is defined by the property of not being conductive.

The applicant's attention is drawn to the fact that claims relating to inventions in respect of which no international search report has been established need not be the subject of an international preliminary examination (Rule 66.1(e) PCT). The applicant is advised that the EPO policy when acting as an International Preliminary Examining Authority is normally not to carry out a preliminary examination on matter which has not been searched. This is the case irrespective of whether or not the claims are amended following receipt of the search report or during any Chapter II procedure. If the application proceeds into the regional phase before the EPO, the applicant is reminded that a search may be carried out during examination before the EPO (see EPO Guideline C-VI, 8.5), should the problems which led to the Article 17(2) declaration be overcome.

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No	
PCT/US2005/032647	

Patent document cited in search report		Publication date	Patent family member(s)		Publication date
US 2004051929	A1	18-03-2004	US	2005002082 A1	06-01-2005
US 2002126364	A1	12-09-2002	NONE		
EP 0694801	A	31-01-1996	DE	69508160 D1	15-04-1999
			DE	69508160 T2	12-08-1999
			JP	8062518 A	08-03-1996
			US	5485304 A	16-01-1996
			US	5646768 A	08-07-1997
			US	5497262 A	05-03-1996